



ANSI C63.19

TEST REPORT

Product Name	HSPA+/UMTS/GPRS/GSM/EDGE Mobile Phone with Bluetooth
Model Name	HUAWEI U8800-51/U8800-51
FCC ID	QISU8800-51
Client	Huawei Technologies Co., Ltd.

TA Technology (Shanghai) Co., Ltd.

TA Technology (Shanghai) Co., Ltd.
Test Report

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GENERAL SUMMARY

Product Name	HSPA+/UMTS/GPRS/GSM/EDGE Mobile Phone with Bluetooth	Model	HUAWEI U8800-51/U8800-51
FCC ID	QISU8800-51		
Report No.	RZA1106-1087HAC01R1		
Client	Huawei Technologies Co., Ltd.		
Manufacturer	Huawei Technologies Co., Ltd.		
Reference Standard(s)	ANSI C63.19-2007: American National Standard Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.		
Conclusion	<p>This portable wireless equipment has been measured in all cases requested by the relevant standards.</p> <p>General Judgment: M3 (RF Emission)</p> <p style="text-align: right;">(Stamp) Date of issue: July 6th, 2011</p> 		
Comment	The test result only responds to the measured sample.		

Approved by Derek Yang
Director

Revised by Jeff. Long
SAR Manager

Performed by Jason Du
SAR Engineer

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1. General Information

1.1. Notes of the Test Report

TA Technology (Shanghai) Co., Ltd. guarantees the reliability of the data presented in this test report, which is the results of measurements and tests performed for the items under test on the date and under the conditions stated in this test report and is based on the knowledge and technical facilities available at TA Technology (Shanghai) Co., Ltd. at the time of execution of the test.

TA Technology (Shanghai) Co., Ltd. is liable to the client for the maintenance by its personnel of the confidentiality of all information related to the items under test and the results of the test. This report only refers to the item that has undergone the test.

This report standalone dose not constitute or imply by its own an approval of the product by the certification Bodies or competent Authorities. This report cannot be used partially or in full for publicity and/or promotional purposes without previous written approval of **TA Technology (Shanghai) Co., Ltd.** and the Accreditation Bodies, if it applies.

If the electrical report is inconsistent with the printed one, it should be subject to the latter.

1.2. Testing Laboratory

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1.3. Applicant Information

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1.4. Manufacturer Information

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1.5. Information of EUT

General Information

Device Type:	Portable Device		
Product Name:	HSPA+/UMTS/GPRS/GSM/EDGE Mobile Phone with Bluetooth		
IMEI:	353568040017457		
Hardware Version:	HD3U880M		
Software Version:	U8800V100R001USAC07B628SP01		
Antenna Type:	Internal Antenna		
Device Operating Configurations:			
Supporting Mode(s):	GSM 850/ GSM 1900; (tested)		
	WCDMA Band II/WCDMA Band V; (tested)		
	GSM900/GSM1800/WCDMA Band I; (untested)		
	WiFi (802.11b/g/n HT20); (untested)		
	Bluetooth; (untested)		
Test Modulation:	(GSM)GMSK; (WCDMA) QPSK		
Device Class:	B		
HSDPA UE Category:	10		
HSUPA UE Category:	6		
GPRS Multislot Class(10):	Max Number of Timeslots in Uplink	2	
	Max Number of Timeslots in Downlink	4	
	Max Total Timeslot	5	
EGPRS Multislot Class(10):	Max Number of Timeslots in Uplink	2	
	Max Number of Timeslots in Downlink	4	
	Max Total Timeslot	5	
Operating Frequency Range(s):	Mode	Tx (MHz)	Rx (MHz)
	GSM 850	824.2 ~ 848.8	869.2 ~ 893.8
	GSM 1900	1850.2 ~ 1909.8	1930.2 ~ 1989.8
	WCDMA Band II	1852.4 ~ 1907.6	1932.4 ~ 1987.6
	WCDMA Band V	826.4 ~ 846.6	871.4 ~ 891.6
Test Channel: (Low - Middle - High)	128-190-251	(GSM 850)	(tested)
	512-661-810	(GSM 1900)	(tested)
	9262 - 9400 - 9538	(WCDMA Band II)	(tested)
	4132 - 4183 - 4233	(WCDMA Band V)	(tested)
Power Class:	GSM 850: 4, tested with power level 5		
	GSM 1900: 1, tested with power level 0		
	WCDMA Band II: 3, tested with power control all up bits		
	WCDMA Band V: 3, tested with power control all up bits		

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Auxiliary Equipment Details

AE:Battery

Model: HB4F1
Manufacturer: Huawei Technologies Co., Ltd.
S/N: LGCB6281I2700252

Equipment Under Test (EUT) is a model of HSPA+/UMTS/GPRS/GSM/EDGE Mobile Phone with Bluetooth. The detail about Mobile phone and Lithium Battery is in chapter 1.5 in this report. It has Personal Wireless Routers (hot spots) function and Proximity Sensor function. HAC is tested for GSM 850, GSM 1900, WCDMA Band II and WCDMA Band V. The device has an internal antenna for GSM/WCDMA Tx/Rx, and the other is BT/WIFI antenna that is used for Tx/Rx. WiFi and Bluetooth modes don't have voice capability, and do not operate in the held to ear mode for providing handset service.

The sample under test was selected by the Client.

Components list please refer to documents of the manufacturer.

1.6. The Ambient Conditions during Test

Temperature	Min. = 18°C, Max. = 28 °C
Relative humidity	Min. = 0%, Max. = 80%
Ground system resistance	< 0.5 Ω
Ambient noise is checked and found very low and in compliance with requirement of standards. Reflection of surrounding objects is minimized and in compliance with requirement of standards.	

1.7. The Total M-rating of each tested band

Mode	Rating
GSM 850	M3
GSM 1900	M3
WCDMA Band II	M4
WCDMA Band V	M4

1.8. Test Date

The test is performed on June 30, 2011.

2. Test Information

2.1. Operational Conditions during Test

2.1.1. General Description of Test Procedures

The phone was tested in all normal configurations for the ear use. The EUT is mounted in the device holder equivalent as for classic dosimeter measurements. The acoustic output of the EUT shall coincide with the center point of the area formed by the dielectric wire and the middle bar of the arch's top frame. The EUT shall be moved vertically upwards until it touches the frame. The fine adjustment is possible by sliding the complete. The EUT holder is on the yellow base plate of the Test Arch phantom. These test configurations are tested at the high, middle and low frequency channels of each applicable operating mode; for example, GSM, WCDMA (UMTS), CDMA and TDMA.

2.1.2. GSM/WCDMA Test Configuration

A communication link is set up with a System Simulator (SS) by air link, and a call is established. The Absolute Radiofrequency Channel Number (ARFCN) is allocated to 128, 190 and 251 in the case of GSM 850, to 512, 661 and 810 in the case of GSM 1900, to 9262, 9400 and 9538 in the case of WCDMA Band II, to 4132, 4183 and 4233 in the case of WCDMA Band V. The EUT is commanded to operate at maximum transmitting power. Using E5515C the power level is set to "5" in SAR of GSM 850, set to "0" in SAR of GSM 1900. Set to all "1's" for WCDMA. The test in the band of GSM 850/1900 and WCDMA Band II/V are performed in the mode of speech transfer function.

2.2. HAC RF Measurements System Configuration

2.2.1. HAC Measurement Set-up

These measurements are performed using the DASY5 automated dosimetric assessment system. It is made by Schmid & Partner Engineering AG (SPEAG) in Zurich, Switzerland. It consists of high precision robotics system (Stäubli), robot controller, Intel Core2 computer, near-field probe, probe alignment sensor. The robot is a six-axis industrial robot performing precise movements. Cell controller systems contain the power supply, robot controller, teach pendant (Joystick) and remote control, and are used to drive the robot motors. The Stäubli Robot is connected to the cell controller to allow software manipulation of the robot. A data acquisition electronic (DAE) circuit performs the signal amplification; signal multiplexing, AD-conversion, offset measurements, mechanical surface detection, collision detection, etc. is connected to the Electro-optical coupler (EOC). The EOC performs the conversion from the optical into digital electric signal of the DAE and transfers data to the PC plug-in card.

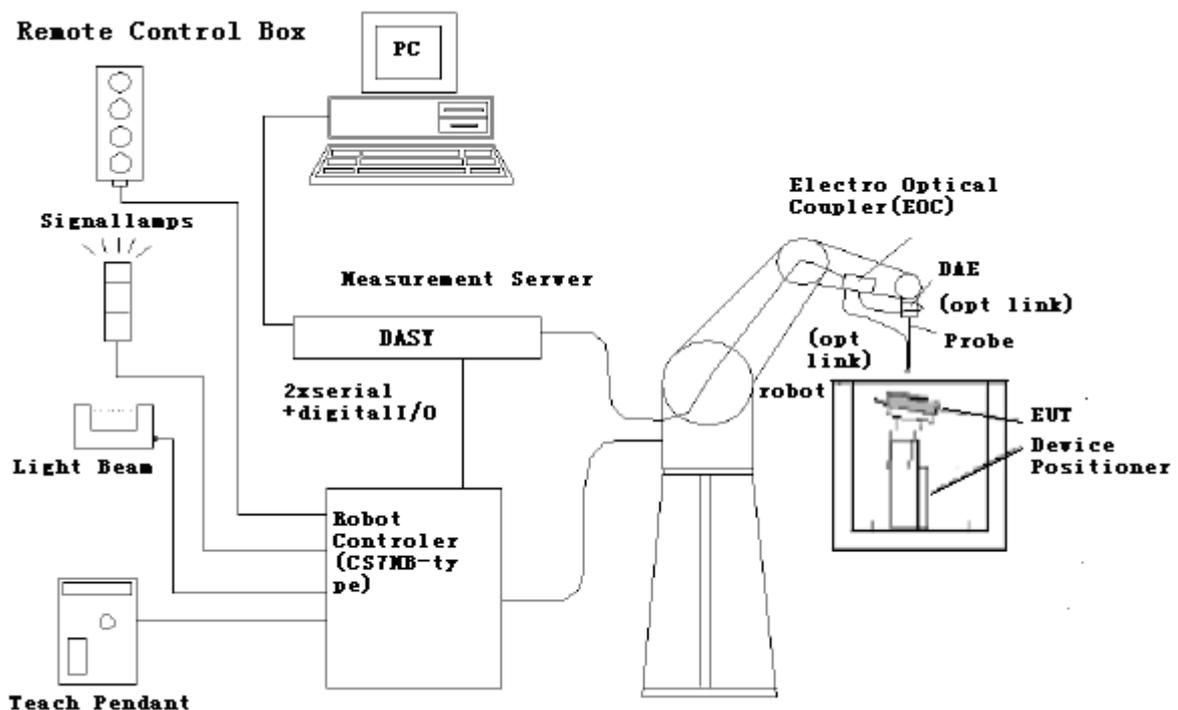


Figure 1 HAC Test Measurement Set-up

The DAE4 consists of a highly sensitive electrometer-grade preamplifier with auto-zeroing, a channel and gain-switching multiplexer, a fast 16 bit AD-converter and a command decoder and control logic unit. Transmission to the PC-card is accomplished through an optical downlink for data and status information and an optical uplink for commands and clock lines. The mechanical probe mounting device includes two different sensor systems for frontal and sidewise probe contacts. They are also used for mechanical surface detection and probe collision detection. The robot uses its own controller with a built in VME-bus computer.

2.2.2. Probe System

The HAC measurements were conducted with the E-Field Probe ER3DV6 and the H-Field Probe H3DV6 (manufactured by SPEAG), designed in the classical triangular configuration and optimized for dosimetric evaluation.

E-Field Probe Description

Construction	One dipole parallel, two dipoles normal to probe axis Built-in shielding against static charges PEEK enclosure material
Calibration	In air from 100 MHz to 3.0 GHz (absolute accuracy $\pm 6.0\%$, $k=2$)
Frequency	40 MHz to > 6 GHz (can be extended to < 20 MHz) Linearity: ± 0.2 dB (100 MHz to 3 GHz)
Directivity	± 0.2 dB in air (rotation around probe axis) ± 0.4 dB in air (rotation normal to probe axis)
Dynamic Range	2 V/m to > 1000 V/m; Linearity: ± 0.2 dB
Dimensions	Overall length: 330 mm (Tip: 16 mm) Tip diameter: 8 mm (Body: 12 mm) Distance from probe tip to dipole centers: 2.5 mm
Application	General near-field measurements up to 6 GHz Field component measurements Fast automatic scanning in phantoms



Figure 2 ER3DV6 E-field Probe

H-Field Probe Description

Construction	Three concentric loop sensors with 3.8 mm loop diameters Resistively loaded detector diodes for linear response Built-in shielding against static charges PEEK enclosure material (resistant to organic solvents, e.g., glycolether)
Frequency	200 MHz to 3 GHz (absolute accuracy $\pm 6.0\%$, $k=2$); Output linearized
Directivity	± 0.2 dB (spherical isotropy error)
Dynamic Range	10 mA/m to 2 A/m at 1 GHz
E-Field Interference	< 10% at 3 GHz (for plane wave)
Dimensions	Overall length: 330 mm (Tip: 40 mm) Tip diameter: 6 mm (Body: 12 mm) Distance from probe tip to dipole centers: 3 mm



Figure 3 H3DV6 H-field Probe

Application	General magnetic near-field measurements up to 3 GHz (in air or liquids) Field component measurements Surface current measurements Low interaction with the measured field
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2.2.3. Test Arch Phantom & Phone Positioner

The Test Arch phantom should be positioned horizontally on a stable surface. Reference markings on the Phantom allow the complete setup of all predefined phantom positions and measurement grids by manually teaching three points in the robot. It enables easy and well defined positioning of the phone and validation dipoles as well as simple teaching of the robot (Dimensions: 370 x 370 x 370 mm).

The Device reference point is set for the EUT at 6.3 mm, the Grid reference point is on the upper surface at the origin of the coordinates, and the “user point \Height Check 0.5 mm” is 0.5mm above the center, allowing verification of the gap of 0.5mm while the probe is positioned there.

The Phone Positioner supports accurate and reliable positioning of any phone with effect on near field $<\pm 0.5$ dB.

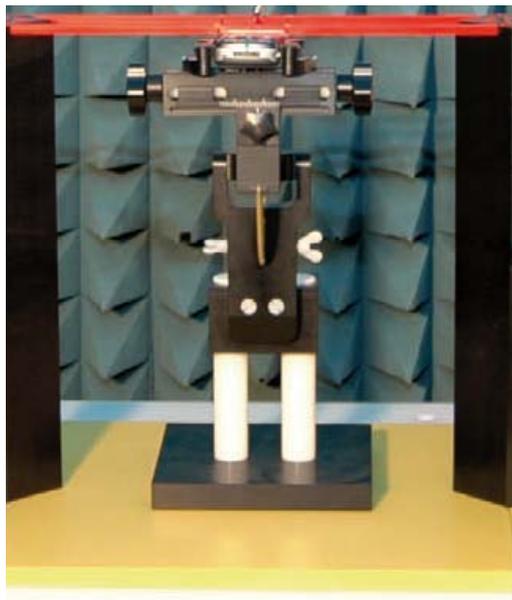


Figure 4 HAC Phantom & Device Holder

2.3. RF Test Procedures

The evaluation was performed with the following procedure:

1. Confirm proper operation of the field probe, probe measurement system and other instrumentation and the positioning system.
2. Position the WD in its intended test position. The gauge block can simplify this positioning. Note that a separate E-field and H-field gauge block will be needed if the center of the probe sensor elements is at different distances from the tip of the probe.
3. Configure the WD normal operation for maximum rated RF output power, at the desired channel and other operating parameters (e.g., test mode), as intended for the test.
4. The center sub-grid shall center on the center of the axial measurement point or the acoustic output, as appropriate. Locate the field probe at the initial test position in the 50 mm by 50 mm grid, which is contained in the measurement plane. If the field alignment method is used, align the probe for maximum field reception.
5. Record the reading.
6. Scan the entire 50 mm by 50 mm region in equally spaced increments and record the reading at each measurement point. The grid is 5 cm by 5 cm area that is divided into 9 evenly sized blocks or sub-grids. The distance between measurement points shall be sufficient to assure the identification of the maximum reading.
7. Identify the five contiguous sub-grids around the center sub-grid with the lowest maximum field strength readings. Thus the six areas to be used to determine the WD's highest emissions are identified and outlined for the final manual scan. Please note that a maximum of five blocks can be excluded for both E-field and H-field measurements for the WD output being measured. Stated another way, the center sub-grid and three others must be common to both the E-field and H-field measurements.
8. Identify the maximum field reading within the non-excluded sub-grids identified in Step 7.
9. Convert the maximum field strength reading identified in Step 8 to V/m or A/m, as appropriate. For probes which require a probe modulation factor, this conversion shall be done using the appropriate probe modulation factor and the calibration.
10. Repeat Step 1 through Step 10 for both the E-field and H-field measurements.
11. Compare this reading to the categories in ANSI C63.19 Clause 7 and record the resulting category. The lowest category number listed in 7.2, Table 7.4, or Table 7.5 obtained in Step 10 for either E- or H-field determines the M category for the audio coupling mode assessment. Record the WD category rating.



Figure 5 WD reference and plane for RF emission measurements

2.4. System Check

Validation Procedure

Place a dipole antenna meeting the requirements given in ANSI C63.19 D.5 in the position normally occupied by the WD. The dipole antenna serves as a known source for an electrical and magnetic output. Position the E-field and H-field probes so that:

The probes and their cables are parallel to the coaxial feed of the dipole antenna.

The probe cables and the coaxial feed of the dipole antenna approach the measurement area from opposite directions.

The center point of the probe element(s) are 10 mm from the closest surface of the dipole elements. Validation was performed to verify that measured E-field and H-field values are within +/-25% from the target reference values provided by the manufacturer. "Values within +/-25% are acceptable. Of which 12% is deviation and 13% is measurement uncertainty."

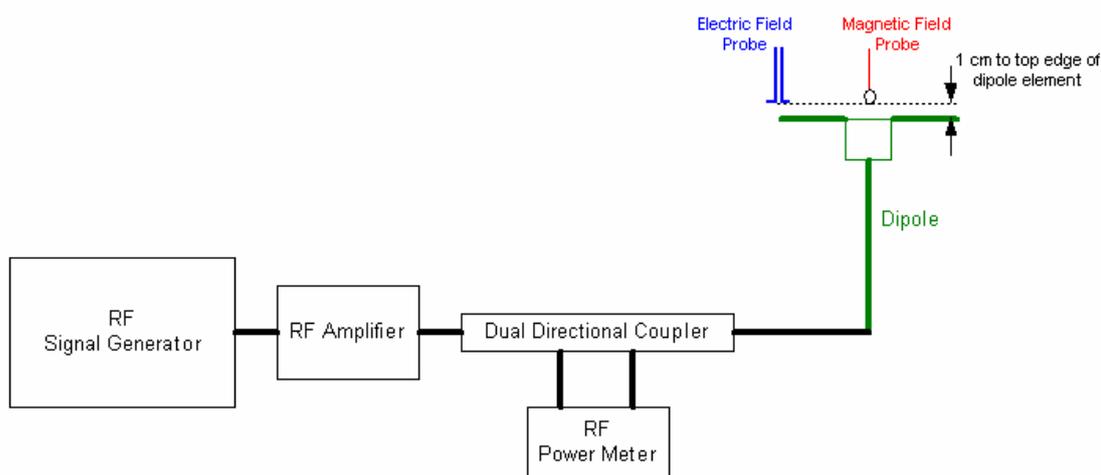


Figure 6 Dipole Validation Setup

Dipole Measurement Summary

E-Field Scan						
Mode	Frequency (MHz)	Input Power (mW)	Measured ¹ Value(V/m)	Target ² Value(V/m)	Deviation ³ (%)	Test Date
CW	835	100	149.2	158.2	5.69	June 30, 2011
CW	1880	100	131.4	142.9	8.05	June 30, 2011
H-Field Scan						
Mode	Frequency (MHz)	Input Power (mW)	Measured ¹ Value(V/m)	Target ² Value(V/m)	Deviation ³ (%)	Test Date
CW	835	100	0.443	0.446	0.67	June 30, 2011
CW	1880	100	0.449	0.475	5.47	June 30, 2011

Notes: 1. please refer to the attachment for detailed measurement data and plot.

2. Target value is provided by SPEAD in the calibration certificate of specific dipoles.

3. Deviation (%) = 100 * (Target value minus Measured value) divided by Target value.

2.5. Probe Modulation Factor

The Probe Modulation Factor (PMF) is defined as the ratio of the field readings for a CW and a modulated signal with the equivalent Field Envelope Peak as defined in ANSI C63.19 (Chapter C.3.1). Calibration shall be made of the modulation response of the probe and its instrumentation chain. This Calibration shall be performed with the field probe, attached to the instrumentation that is to be used with it during the measurement. The response of the probe system to a CW field at the frequency(s) of interest is compared to its response to a modulated signal with equal peak amplitude. The field level of the test signals shall be more than 10dB above the ambient level and the noise floor of the instrumentation being used. The ratio of the CW reading to that taken with a modulated field shall be applied to the readings taken of modulated fields of the specified type.

Modulation Factor Test Procedure

This may be done using the following procedure:

1. Fix the field probe in a set location relative to a field generating device, such as the reference dipole antenna.
2. Illuminate the probe using the wireless device connected to the reference dipole with a test signal at the intended measurement frequency, Ensure there is sufficient field coupling between the probe and the antenna so the resulting reading is greater than 10 dB above the probe system noise floor but within the systems operating range.
3. Record the amplitude applied to the antenna during transmission and the field strength measured by the E-field probe located near the tip of the dipole antenna
4. Replace the wireless device with an RF signal generator producing an unmodulated CW signal and set to the wireless device operating frequency.
5. Set the amplitude of the unmodulated signal to equal that recorded from the wireless device.
6. Record the reading of the probe measurement system of the unmodulated signal.
7. The ratio, in linear units, of the probe reading in Step 6 to the reading in Step 3 is the E-field modulation factor. $PMF_E = E_{CW} / E_{mod}$ ($PMF_H = H_{CW} / H_{mod}$)
8. Repeat the previous steps using the H-field probe, except locate the probe at the center of the dipole.

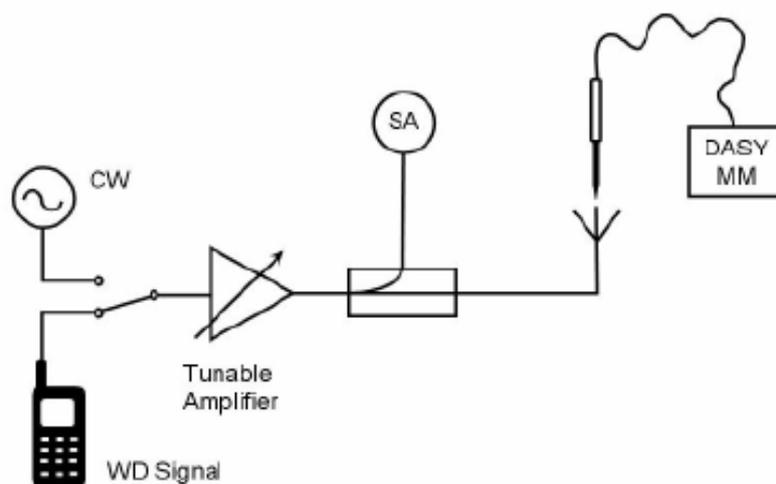


Figure 7 Probe Modulation Factor Test Setup

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PMF

Band	E-Field Probe Modulation Factor	H-Field Probe Modulation Factor
GSM 850	2.81	2.75
GSM 1900	2.84	2.84
WCDMA Band II	1.02	1.01
WCDMA Band V	1.03	1.01

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2.6. Conducted Output Power Measurement

Summary

The DUT is tested using an E5515C communications tester as controller unit to set test channels and maximum output power to the DUT, as well as for measuring the conducted power. Conducted output power was measured using an integrated RF connector and attached RF cable. This result contains conducted output power for the EUT.

Conducted Power Results

GSM 850	Conducted Power(dBm)		
	Channel 128	Channel 190	Channel 251
Test Results	34.12	34.15	33.96
GSM 1900	Conducted Power(dBm)		
	Channel 512	Channel 661	Channel 810
Test Results	30.72	30.88	30.91
WCDMA Band II	Conducted Power(dBm)		
	Channel 9262	Channel 9400	Channel 9538
12.2kbps RMC	23.59	23.39	23.27
64kbps RMC	23.62	23.35	23.22
144kbps RMC	23.64	23.33	23.21
384kbps RMC	23.61	23.34	23.25
WCDMA Band II HSDPA	Conducted Power(dBm)		
	Channel 9262	Channel 9400	Channel 9538
Sub - Test 1	23.05	22.78	22.62
Sub - Test 2	22.72	22.68	22.34
Sub - Test 3	22.15	22.12	21.79
Sub - Test 4	22.13	22.11	21.71
WCDMA Band V	Conducted Power(dBm)		
	Channel 4132	Channel 4183	Channel 4233
12.2kbps RMC	23.96	24.41	24.23
64kbps RMC	23.92	24.23	24.26
144kbps RMC	23.98	24.36	24.25
384kbps RMC	23.94	24.39	24.22
WCDMA Band V HSDPA	Conducted Power(dBm)		
	Channel 4132	Channel 4132	Channel 4132
Sub - Test 1	23.92	24.32	24.23
Sub - Test 2	23.96	24.18	24.26
Sub - Test 3	23.44	23.72	23.68
Sub - Test 4	23.48	23.75	23.81

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3. Test Results

3.1. ANSI C63.19-2007 Limits

Category		Telephone RF parameters < 960 MHz			
Near field	AWF	E-field emissions		H-field emissions	
Category M1/T1	0	631.0 to 1122.0	V/m	1.91 to 3.39	A/m
	-5	473.2 to 841.4	V/m	1.43 to 2.54	A/m
Category M2/T2	0	354.8 to 631.0	V/m	1.07 to 1.91	A/m
	-5	266.1 to 473.2	V/m	0.80 to 1.43	A/m
Category M3/T3	0	199.5 to 354.8	V/m	0.60 to 1.07	A/m
	-5	149.6 to 266.1	V/m	0.45 to 0.80	A/m
Category M4/T4	0	< 199.5	V/m	< 0.60	A/m
	-5	< 149.6	V/m	< 0.45	A/m
Category		Telephone RF parameters > 960 MHz			
Near field	AWF	E-field emissions		H-field emissions	
Category M1/T1	0	199.5 to 354.8	V/m	0.60 to 1.07	A/m
	-5	149.6 to 266.1	V/m	0.45 to 0.80	A/m
Category M2/T2	0	112.2 to 199.5	V/m	0.34 to 0.60	A/m
	-5	84.1 to 149.6	V/m	0.25 to 0.45	A/m
Category M3/T3	0	63.1 to 112.2	V/m	0.19 to 0.34	A/m
	-5	47.3 to 84.1	V/m	0.14 to 0.25	A/m
Category M4/T4	0	< 63.1	V/m	< 0.19	A/m
	-5	< 47.3	V/m	< 0.14	A/m

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3.2. Summary Test Results

GSM 850 Results

E-Field					
Channel	Frequency (MHz)	Peak Field (V/m)	Power Drift (dB)	Rating	Graph Results
High/251	848.8	171.1	-0.041	M3	Figure 12
Middle/190	836.6	181.3	-0.124	M3	Figure 13
Low/128	824.2	167.7	0.026	M3	Figure 14
H-Field					
Channel	Frequency (MHz)	Peak Field (A/m)	Power Drift (dB)	Rating	Graph Results
High/251	848.8	0.244	-0.037	M4	Figure 15
Middle/190	836.6	0.259	-0.040	M4	Figure 16
Low/128	824.2	0.248	0.015	M4	Figure 17

GSM 1900 Results

E-Field					
Channel	Frequency (MHz)	Peak Field (V/m)	Power Drift (dB)	Rating	Graph Results
High/810	1909.8	59.4	-0.009	M3	Figure 18
Middle/661	1880	57.0	-0.031	M3	Figure 19
Low/512	1850.2	61.6	0.009	M3	Figure 20
H-Field					
Channel	Frequency (MHz)	Peak Field (A/m)	Power Drift (dB)	Rating	Graph Results
High/810	1909.8	0.152	0.048	M3	Figure 21
Middle/661	1880	0.157	0.102	M3	Figure 22
Low/512	1850.2	0.169	0.000	M3	Figure 23

WCDMA Band II Results

WCDMA Band II E-Field					
Channel	Frequency (MHz)	Peak Field (V/m)	Power Drift (dB)	Rating	Graph Results
High/9538	1907.6	27.9	0.016	M4	Figure 24
Middle/9400	1880	24.9	0.134	M4	Figure 25
Low/9262	1852.4	28.0	0.051	M4	Figure 26
WCDMA Band II +HSDPA E-Field					
Channel	Frequency (MHz)	Peak Field (V/m)	Power Drift (dB)	Rating	Graph Results
High/9538	1907.6	26.6	0.140	M4	Figure 27

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Middle/9400	1880	25.0	-0.010	M4	Figure 28
Low/9262	1852.4	26.3	-0.060	M4	Figure 29
WCDMA Band II H-Field					
Channel	Frequency (MHz)	Peak Field (A/m)	Power Drift (dB)	Rating	Graph Results
High/9538	1907.6	0.071	-0.018	M4	Figure 30
Middle/9400	1880	0.071	-0.080	M4	Figure 31
Low/9262	1852.4	0.078	-0.035	M4	Figure 32
WCDMA Band II +HSDPA H-Field					
Channel	Frequency (MHz)	Peak Field (A/m)	Power Drift (dB)	Rating	Graph Results
High/9538	1907.6	0.067	-0.002	M4	Figure 33
Middle/9400	1880	0.067	-0.040	M4	Figure 34
Low/9262	1852.4	0.072	0.006	M4	Figure 35

WCDMA Band V Results

WCDMA Band V E-Field					
Channel	Frequency (MHz)	Peak Field (V/m)	Power Drift (dB)	Rating	Graph Results
High/4233	846.6	62.9	-0.038	M4	Figure 36
Middle/4183	836.6	69.2	0.021	M4	Figure 37
Low/4132	826.4	58.1	0.058	M4	Figure 38
WCDMA Band V +HSDPA E-Field					
Channel	Frequency (MHz)	Peak Field (V/m)	Power Drift (dB)	Rating	Graph Results
High/4233	846.6	63.3	-0.025	M4	Figure 39
Middle/4183	836.6	66.9	0.048	M4	Figure 40
Low/4132	826.4	57.0	-0.047	M4	Figure 41
WCDMA Band V H-Field					
Channel	Frequency (MHz)	Peak Field (A/m)	Power Drift (dB)	Rating	Graph Results
High/4233	846.6	0.092	-0.003	M4	Figure 42
Middle/4183	836.6	0.104	0.009	M4	Figure 43
Low/4132	826.4	0.086	0.068	M4	Figure 44
WCDMA Band V +HSDPA H-Field					
Channel	Frequency (MHz)	Peak Field (A/m)	Power Drift (dB)	Rating	Graph Results
High/4233	846.6	0.091	-0.023	M4	Figure 45
Middle/4183	836.6	0.098	-0.030	M4	Figure 46
Low/4132	826.4	0.084	0.055	M4	Figure 47

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4. Measurement Uncertainty

No.	Error source	Type	Uncertainty Value (%)	Prob. Dist.	k	c_{iE}	c_{iH}	Standard Uncertainty (%) u_i (%) E	Standard Uncertainty (%) u_i (%) H	Degree of freedom V_{eff} or v_i
Measurement System										
1	Probe Calibration	B	5.1	N	1	1	1	5.1	5.1	∞
2	Axial Isotropy	B	4.7	R	$\sqrt{3}$	1	1	2.7	2.7	∞
3	Sensor Displacement	B	16.5	R	$\sqrt{3}$	1	0.145	9.5	1.4	∞
4	Boundary Effects	B	2.4	R	$\sqrt{3}$	1	1	1.4	1.4	∞
5	Linearity	B	4.7	R	$\sqrt{3}$	1	1	2.7	2.7	∞
6	Scaling to Peak Envelope Power	B	2.0	R	$\sqrt{3}$	1	1	1.2	1.2	∞
7	System Detection Limit	B	1.0	R	$\sqrt{3}$	1	1	0.6	0.6	∞
8	Readout Electronics	B	0.3	N	1	1	1	0.3	0.3	∞
9	Response Time	B	0.8	R	$\sqrt{3}$	1	1	0.5	0.5	∞
10	Integration Time	B	2.6	R	$\sqrt{3}$	1	1	1.5	1.5	∞
11	RF Ambient Conditions	B	3.0	R	$\sqrt{3}$	1	1	1.7	1.7	∞
12	RF Reflections	B	12.0	R	$\sqrt{3}$	1	1	6.9	6.9	∞
13	Probe Positioner	B	1.2	R	$\sqrt{3}$	1	0.67	0.7	0.5	∞
14	Probe Positioning	A	4.7	R	$\sqrt{3}$	1	0.67	2.7	1.8	∞
15	Extra. And Interpolation	B	1.0	R	$\sqrt{3}$	1	1	0.6	0.6	∞
Test Sample Related										
16	Device Positioning Vertical	B	4.7	R	$\sqrt{3}$	1	0.67	2.7	1.8	∞
17	Device Positioning Lateral	B	1.0	R	$\sqrt{3}$	1	1	0.6	0.6	∞
18	Device Holder and Phantom	B	2.4	R	$\sqrt{3}$	1	1	1.4	1.4	∞

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19	Power Drift	B	5.0	R	$\sqrt{3}$	1	1	2.9	2.9	∞
Phantom and Setup related										
20s	Phantom Thickness	B	2.4	R	$\sqrt{3}$	1	0.67	1.4	0.9	∞
Combined standard uncertainty(%)								14.7	10.9	
Expanded Std. uncertainty on power (K=2)								29.4	21.8	
Expanded Std. uncertainty on field (K=2)								14.7	10.9	

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5. Main Test Instruments

No.	Name	Type	Serial Number	Calibration Date	Valid Period
01	Power meter	Agilent E4417A	GB41291714	March 12, 2011	One year
02	Power sensor	Agilent N8481H	MY50350004	September 26, 2010	One year
03	Signal Generator	HP 8341B	2730A00804	September 13, 2010	One year
04	Amplifier	IXA-020	0401	No Calibration Requested	
05	BTS	E5515C	MY48360988	December 3, 2010	One year
06	E-Field Probe	ER3DV6	2428	October 20, 2009	Two years
07	H-Field Probe	H3DV6	6260	October 20, 2009	Two years
08	DAE	DAE4	871	November 18, 2010	One year
09	Validation Kit 835MHz	CD835V3	1133	April 22, 2009	Three years
10	Validation Kit 1880MHz	CD1880V3	1135	January 13, 2010	Three years

*****END OF REPORT BODY*****

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ANNEX A: System Check Results

HAC_System Performance Check at 835MHz_E

DUT: Dipole 835 MHz; Type: CD835V3; SN:1133

Date/Time: 6/30/2011 5:42:32 PM

Communication System: CW; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch; Type: SD HAC P01 BA;

Measurement SW: DASY5, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 149.2 V/m

Probe Modulation Factor = 1.00

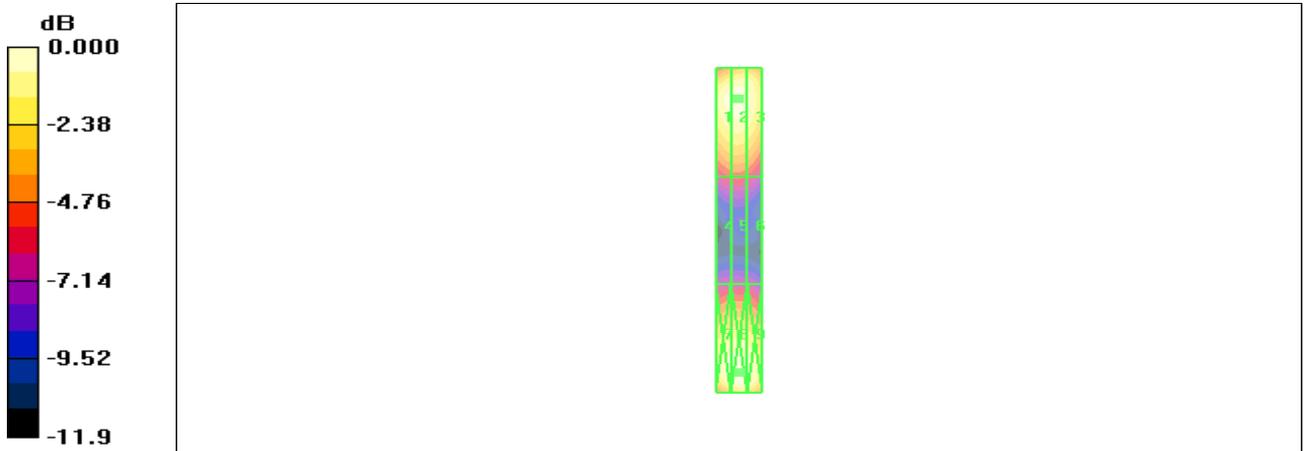
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 100.7 V/m; Power Drift = -0.066 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 147.0 M4	Grid 2 149.2 M4	Grid 3 143.9 M4
Grid 4 83.4 M4	Grid 5 85.0 M4	Grid 6 81.1 M4
Grid 7 148.8 M4	Grid 8 154.0 M4	Grid 9 148.9 M4



0 dB = 154.0V/m

Figure 8 System Performance Check 835MHz_E

TA Technology (Shanghai) Co., Ltd. Test Report

HAC_System Performance Check at 835MHz_H

DUT: Dipole 835 MHz; Type: CD835V3; SN: 1133

Date/Time: 6/30/2011 4:27:58 PM

Communication System: CW; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch; Type: SD HAC P01 BA;

Measurement SW: DASY5, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.443 A/m

Probe Modulation Factor = 1.00

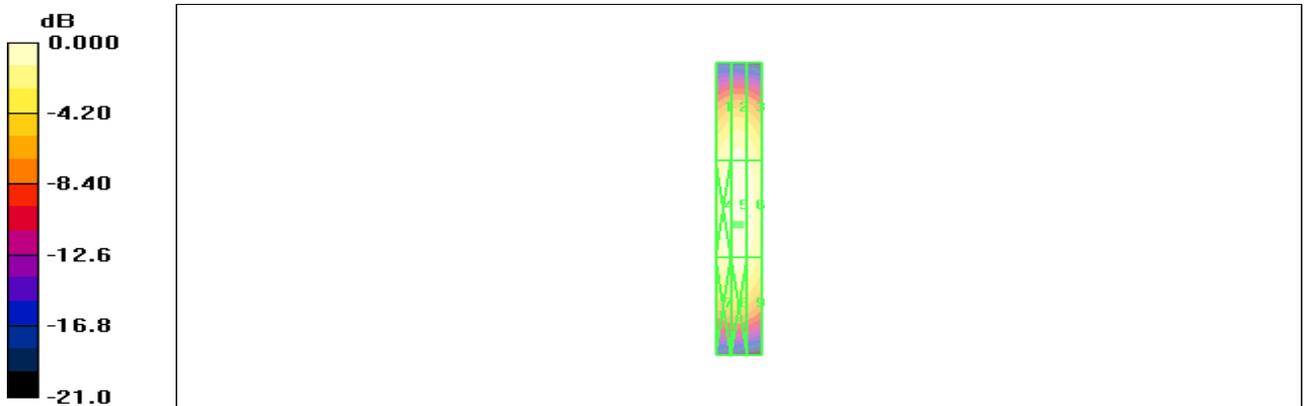
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.464 A/m; Power Drift = 0.019 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.391 M4	Grid 2 0.408 M4	Grid 3 0.384 M4
Grid 4 0.427 M4	Grid 5 0.443 M4	Grid 6 0.414 M4
Grid 7 0.397 M4	Grid 8 0.410 M4	Grid 9 0.381 M4



0 dB = 0.443A/m

Figure 9 System Performance Check 835MHz_H

TA Technology (Shanghai) Co., Ltd. Test Report

HAC_System Performance Check at 1880MHz_E

DUT: Dipole 1880 MHz; Type: CD1880V3; SN:1135

Date/Time: 6/30/2011 3:12:34 PM

Communication System: CW; Frequency: 1880 MHz;Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch; Type: SD HAC P01 BA;

Measurement SW: DASY5, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 131.4 V/m

Probe Modulation Factor = 1.00

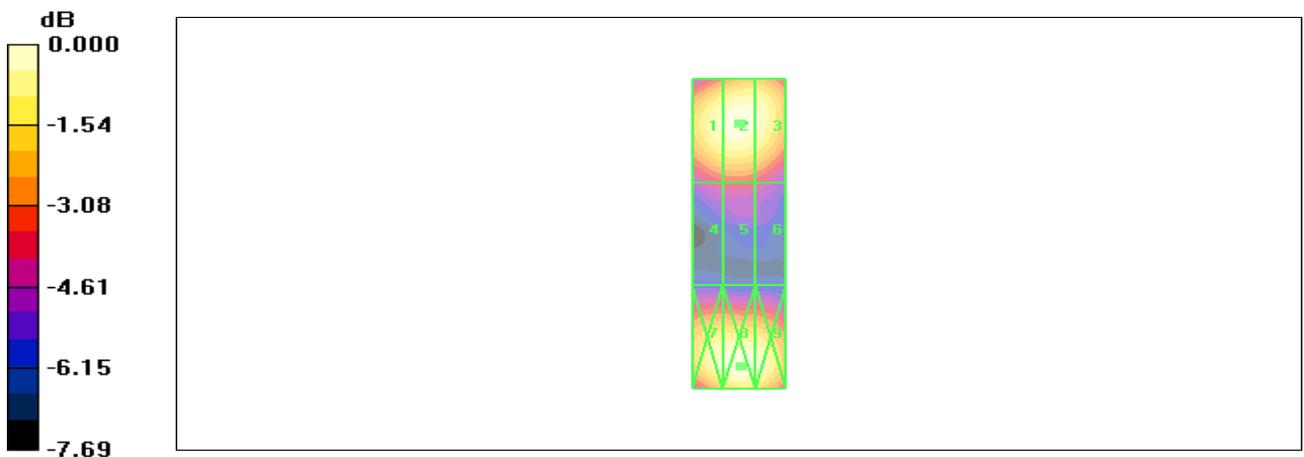
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 151.0 V/m; Power Drift = -0.047 dB

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak E-field in V/m

Grid 1 128.5 M2	Grid 2 131.4 M2	Grid 3 128.5 M2
Grid 4 87.5 M3	Grid 5 89.7 M3	Grid 6 86.2 M3
Grid 7 128.7 M2	Grid 8 134.0 M2	Grid 9 130.3 M2



0 dB = 134.0V/m

Figure 10 System Performance Check 1880MHz_E

TA Technology (Shanghai) Co., Ltd. Test Report

HAC_System Performance Check at 1880MHz_H

DUT: Dipole 1880 MHz; Type: CD1880V3; SN:1135

Date/Time: 6/30/2011 1:50:22 PM

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch; Type: SD HAC P01 BA;

Measurement SW: DASY5, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to Dipole = 10mm/Hearing Aid

Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.449 A/m

Probe Modulation Factor = 1.00

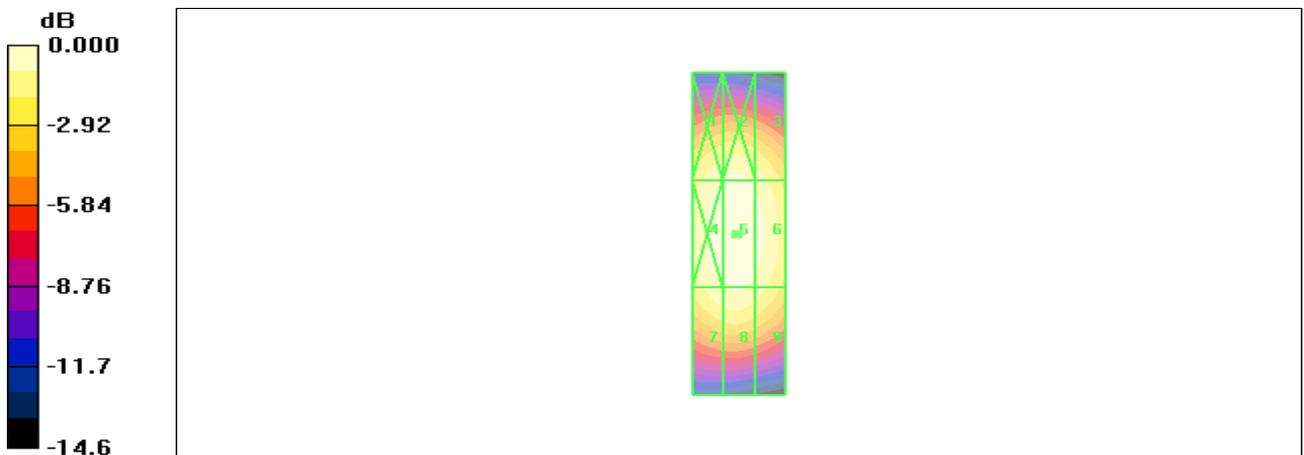
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.472 A/m; Power Drift = -0.005 dB

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.400 M2	0.413 M2	0.387 M2
Grid 4	Grid 5	Grid 6
0.435 M2	0.449 M2	0.422 M2
Grid 7	Grid 8	Grid 9
0.397 M2	0.410 M2	0.384 M2



0 dB = 0.449A/m

Figure 11 System Performance Check 1880MHz_H

ANNEX B: Graph Results

HAC RF E-Field GSM 850 High

Date/Time: 6/30/2011 9:11:49 PM

Communication System: GSM850; Frequency: 848.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device High/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 171.1 V/m

Probe Modulation Factor = 2.81

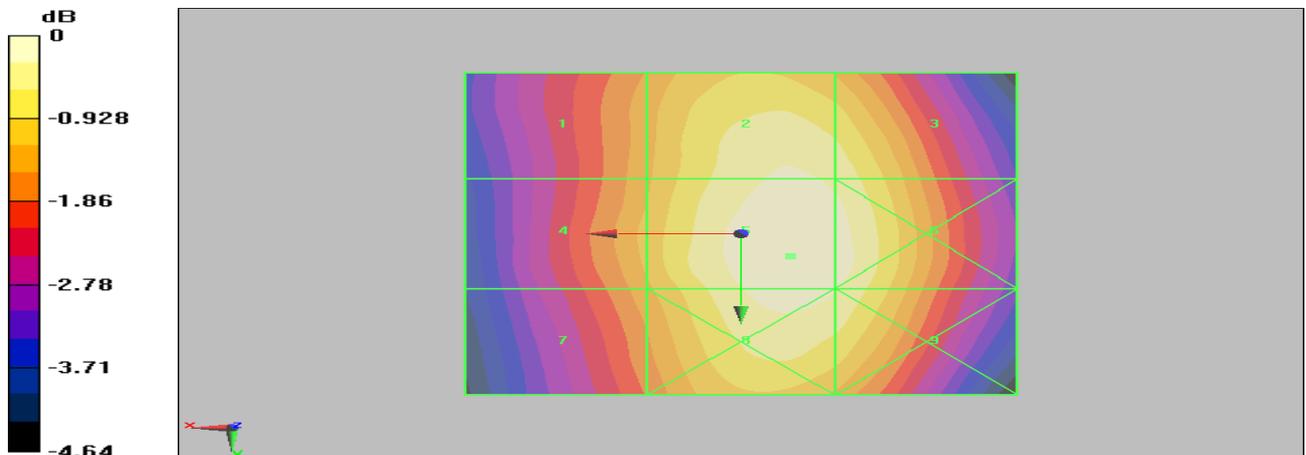
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 78.5 V/m; Power Drift = -0.041 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1 147.6 M4	Grid 2 166.2 M3	Grid 3 163.7 M3
Grid 4 150.5 M3	Grid 5 171.1 M3	Grid 6 168.4 M3
Grid 7 147.2 M4	Grid 8 168.3 M3	Grid 9 165.6 M3



0 dB = 171.1V/m

Figure 12 HAC RF E-Field GSM 850 Channel 251

TA Technology (Shanghai) Co., Ltd. Test Report

HAC RF E-Field GSM 850 Middle

Date/Time: 6/30/2011 9:06:22 PM

Communication System: GSM850; Frequency: 836.6 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Middle/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 181.3 V/m

Probe Modulation Factor = 2.81

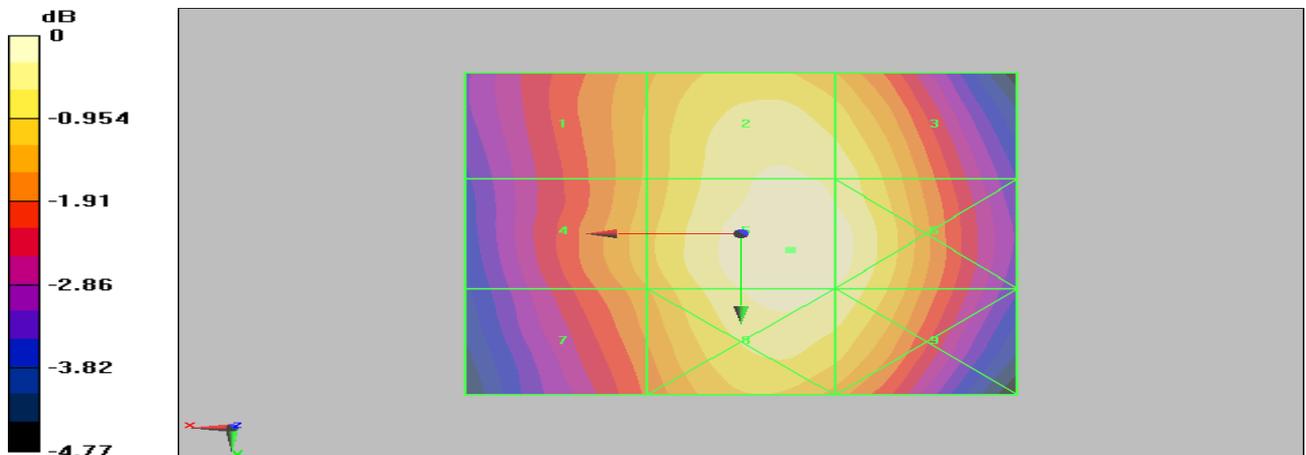
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 84.2 V/m; Power Drift = -0.124 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1 157.9 M3	Grid 2 175.9 M3	Grid 3 173.1 M3
Grid 4 160.7 M3	Grid 5 181.3 M3	Grid 6 178.3 M3
Grid 7 156.4 M3	Grid 8 178.1 M3	Grid 9 174.8 M3



0 dB = 181.3V/m

Figure 13 HAC RF E-Field GSM 850 Channel 190

HAC RF E-Field GSM 850 Low

Date/Time: 6/30/2011 9:17:12 PM

Communication System: GSM850; Frequency: 824.2 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Low/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 167.7 V/m

Probe Modulation Factor = 2.81

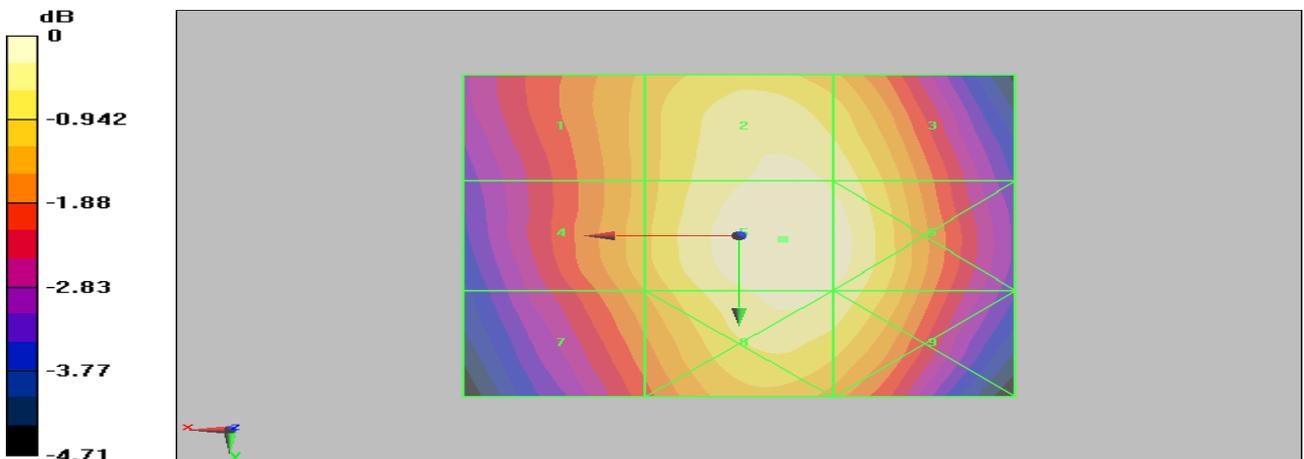
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 77 V/m; Power Drift = 0.026 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1 148.0 M4	Grid 2 163.9 M3	Grid 3 160.8 M3
Grid 4 149.3 M4	Grid 5 167.7 M3	Grid 6 165.1 M3
Grid 7 145.4 M4	Grid 8 164.2 M3	Grid 9 161.4 M3



0 dB = 167.7V/m

Figure 14 HAC RF E-Field GSM 850 Channel 128

TA Technology (Shanghai) Co., Ltd. Test Report

HAC RF H-Field GSM 850 High

Date/Time: 6/30/2011 7:08:34 PM

Communication System: GSM850; Frequency: 848.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

H Scan - H3DV6 - 2007: 15 mm from Probe High/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.244 A/m

Probe Modulation Factor = 2.75

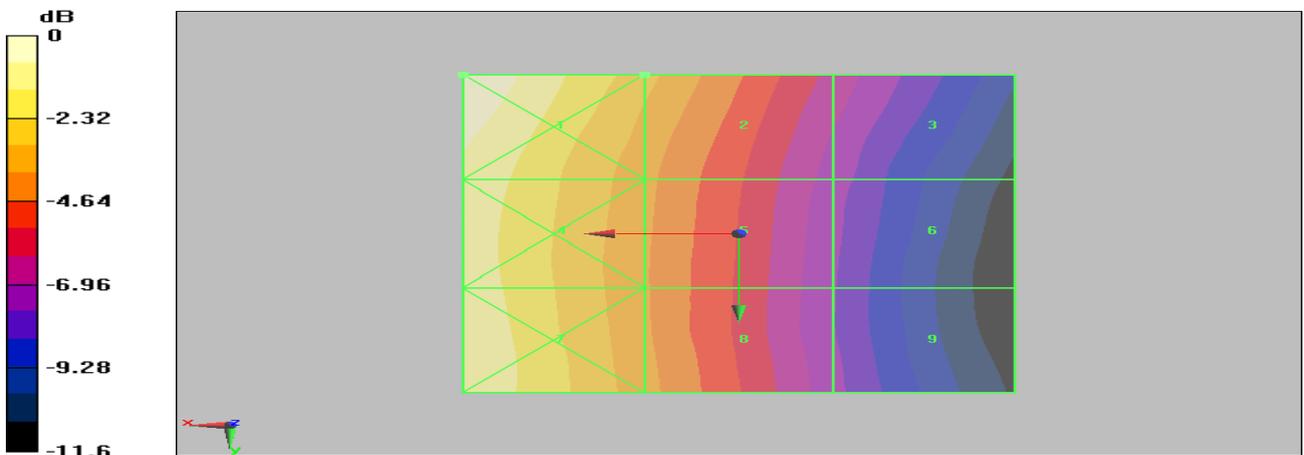
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.068 A/m; Power Drift = -0.037 dB

Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak H-field in A/m

Grid 1 0.337 M4	Grid 2 0.244 M4	Grid 3 0.161 M4
Grid 4 0.303 M4	Grid 5 0.222 M4	Grid 6 0.146 M4
Grid 7 0.306 M4	Grid 8 0.224 M4	Grid 9 0.143 M4



0 dB = 0.337A/m

DFigure 15 HAC RF H-Field GSM 850Channel 251

TA Technology (Shanghai) Co., Ltd. Test Report

HAC RF H-Field GSM 850 Middle

Date/Time: 6/30/2011 7:03:17 PM

Communication System: GSM850; Frequency: 836.6 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

H Scan - H3DV6 - 2007: 15 mm from Probe Middle/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.259 A/m

Probe Modulation Factor = 2.75

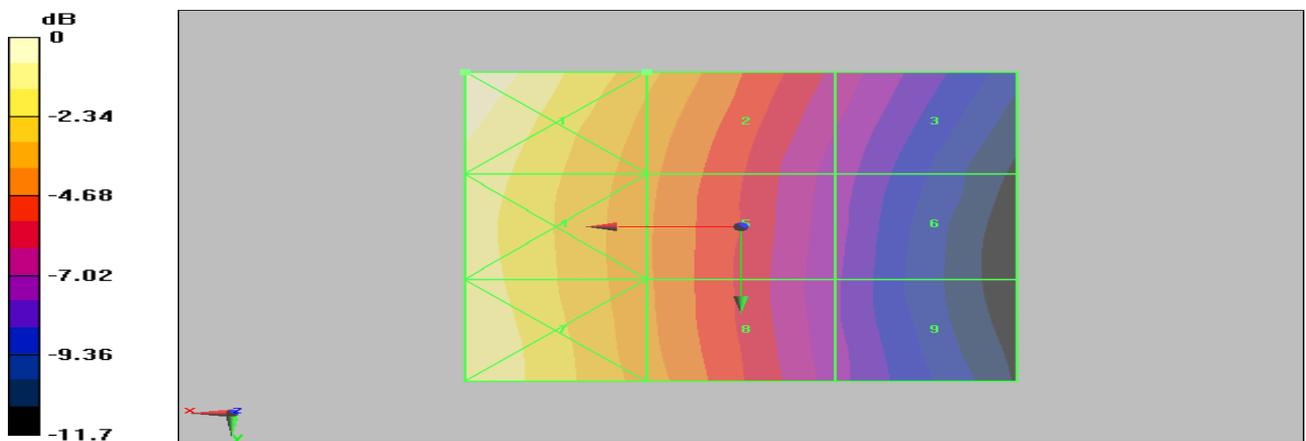
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.072 A/m; Power Drift = -0.040 dB

Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak H-field in A/m

Grid 1 0.359 M4	Grid 2 0.259 M4	Grid 3 0.171 M4
Grid 4 0.320 M4	Grid 5 0.236 M4	Grid 6 0.155 M4
Grid 7 0.329 M4	Grid 8 0.240 M4	Grid 9 0.153 M4



0 dB = 0.359A/m

Figure 16 HAC RF H-Field GSM 850 Channel 190

TA Technology (Shanghai) Co., Ltd. Test Report

HAC RF H-Field GSM 850 Low

Date/Time: 6/30/2011 7:13:56 PM

Communication System: GSM850; Frequency: 824.2 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

H Scan - H3DV6 - 2007: 15 mm from Probe Low/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.248 A/m

Probe Modulation Factor = 2.75

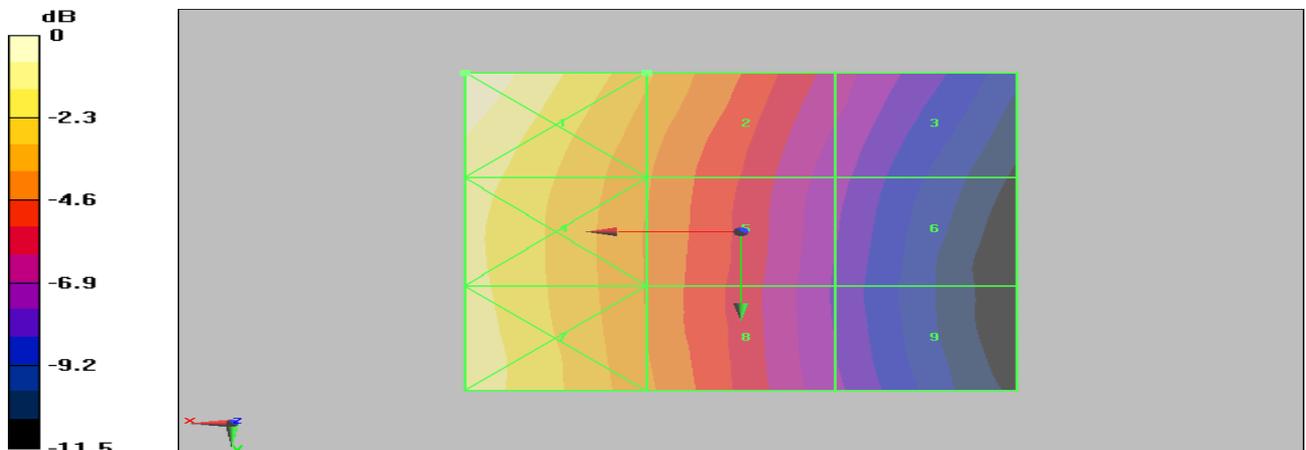
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.069 A/m; Power Drift = 0.015 dB

Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak H-field in A/m

Grid 1 0.346 M4	Grid 2 0.248 M4	Grid 3 0.165 M4
Grid 4 0.304 M4	Grid 5 0.225 M4	Grid 6 0.149 M4
Grid 7 0.309 M4	Grid 8 0.227 M4	Grid 9 0.147 M4



0 dB = 0.346A/m

Figure 17 HAC RF H-Field GSM 850 Channel 128

TA Technology (Shanghai) Co., Ltd. Test Report

HAC RF E-Field GSM 1900 High

Date/Time: 6/30/2011 9:28:29 PM

Communication System: PCS 1900; Frequency: 1909.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device High/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 59.4 V/m

Probe Modulation Factor = 2.84

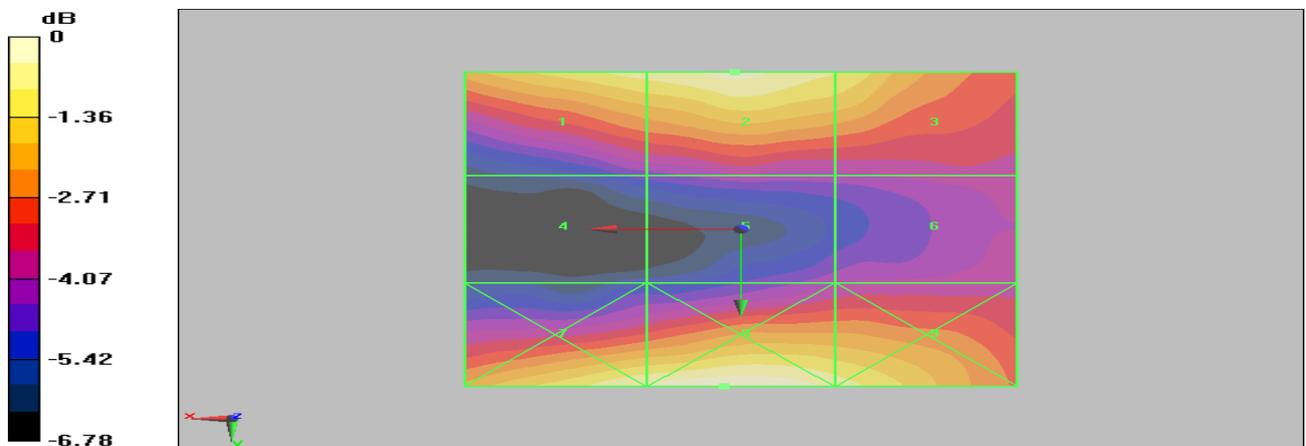
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 9.93 V/m; Power Drift = -0.009 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
57 M3	59.4 M3	55.5 M3
Grid 4	Grid 5	Grid 6
35.5 M4	38.1 M4	40 M4
Grid 7	Grid 8	Grid 9
59.4 M3	61.3 M3	57.2 M3



0 dB = 61.3V/m

Figure 18 HAC RF E-Field GSM 1900 Channel 810

TA Technology (Shanghai) Co., Ltd. Test Report

HAC RF E-Field GSM 1900 Middle

Date/Time: 6/30/2011 9:23:00 PM

Communication System: PCS 1900; Frequency: 1880 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Middle/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 57 V/m

Probe Modulation Factor = 2.84

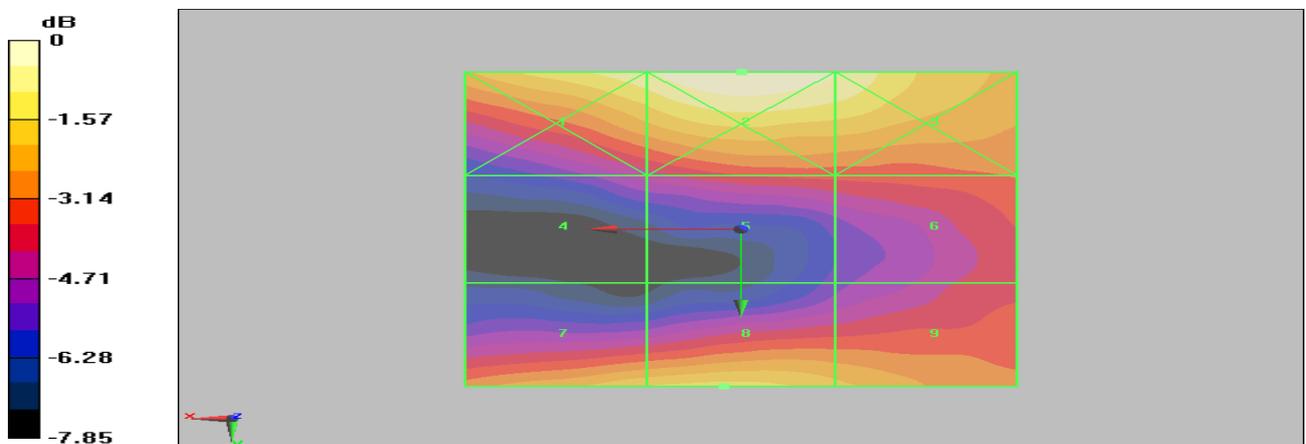
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 11.1 V/m; Power Drift = -0.031 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
62.2 M3	66.3 M3	62.9 M3
Grid 4	Grid 5	Grid 6
39.7 M4	44.4 M4	46.5 M4
Grid 7	Grid 8	Grid 9
55.7 M3	57 M3	53.4 M3



0 dB = 66.3V/m

Figure 19 HAC RF E-Field GSM 1900 Channel 661

TA Technology (Shanghai) Co., Ltd. Test Report

HAC RF E-Field GSM 1900 Low

Date/Time: 6/30/2011 9:33:48 PM

Communication System: PCS 1900; Frequency: 1850.2 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Low/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 61.6 V/m

Probe Modulation Factor = 2.84

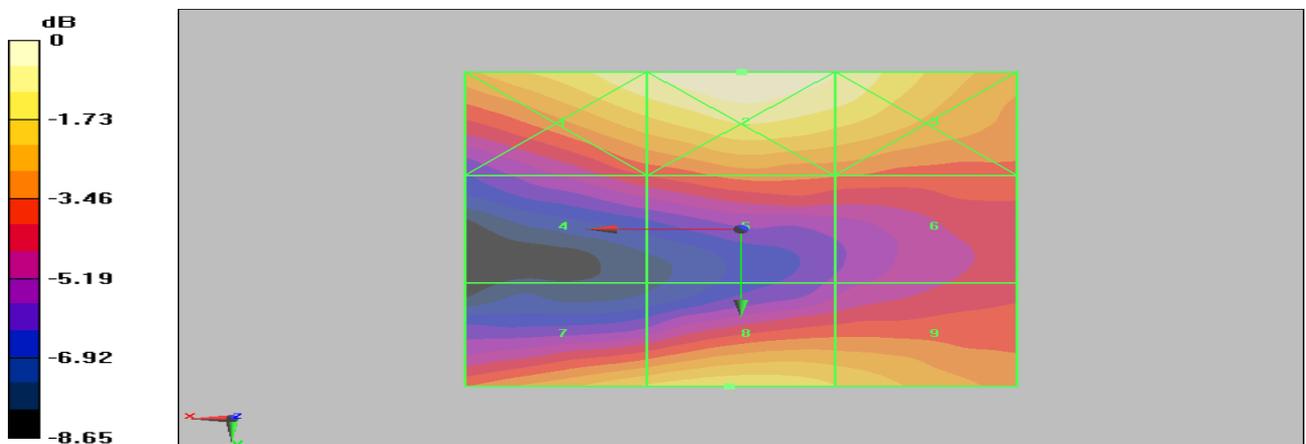
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 13.2 V/m; Power Drift = 0.009 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
66.9 M3	71 M3	66.8 M3
Grid 4	Grid 5	Grid 6
44.7 M4	49.1 M3	48 M3
Grid 7	Grid 8	Grid 9
59.1 M3	61.6 M3	58.5 M3



0 dB = 71V/m

Figure 20 HAC RF E-Field GSM 1900 Channel 512

TA Technology (Shanghai) Co., Ltd. Test Report

HAC RF H-Field GSM 1900 High

Date/Time: 6/30/2011 7:24:43 PM

Communication System: PCS 1900; Frequency: 1909.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

H Scan - H3DV6 - 2007: 15 mm from Probe High/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.152 A/m

Probe Modulation Factor = 2.84

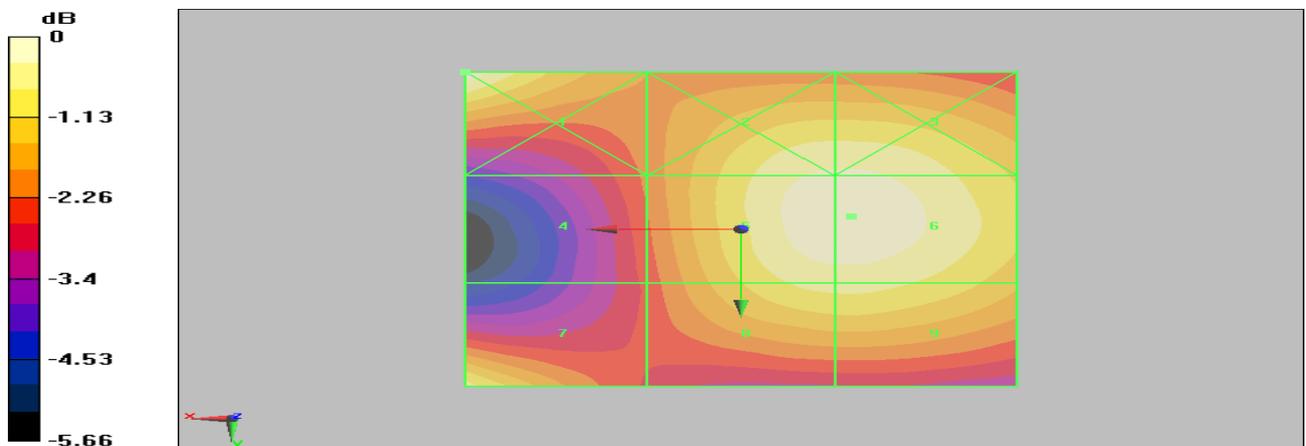
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.057 A/m; Power Drift = 0.048 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak H-field in A/m

Grid 1 0.154 M3	Grid 2 0.149 M3	Grid 3 0.149 M3
Grid 4 0.120 M4	Grid 5 0.152 M3	Grid 6 0.152 M3
Grid 7 0.145 M3	Grid 8 0.144 M3	Grid 9 0.144 M3



0 dB = 0.154A/m

Figure 21 HAC RF H-Field GSM 1900 Channel 810

HAC RF H-Field GSM 1900 Middle

Date/Time: 6/30/2011 7:19:24 PM

Communication System: PCS 1900; Frequency: 1880 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

H Scan - H3DV6 - 2007: 15 mm from Probe Middle/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.157 A/m

Probe Modulation Factor = 2.84

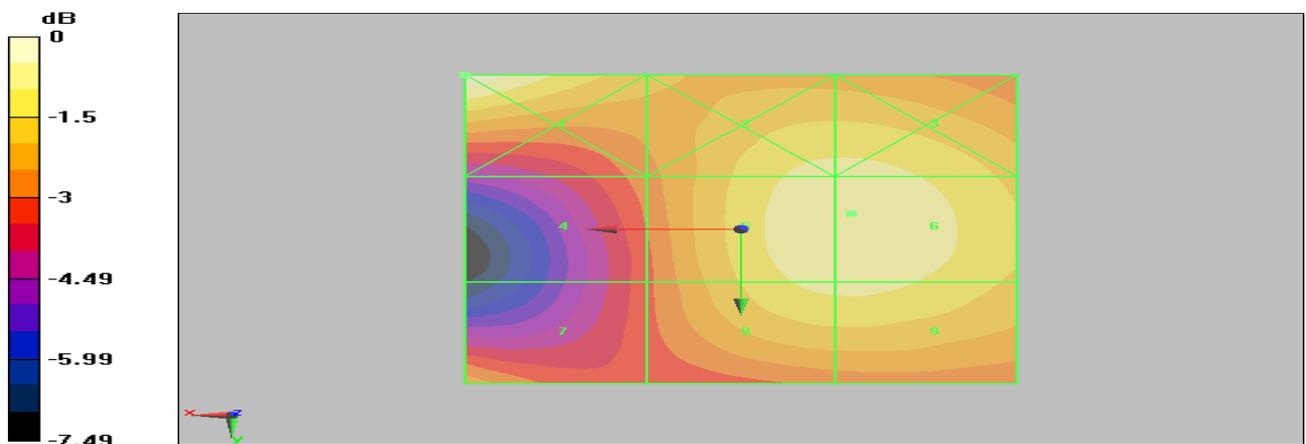
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.060 A/m; Power Drift = 0.102 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak H-field in A/m

Grid 1 0.169 M3	Grid 2 0.154 M3	Grid 3 0.154 M3
Grid 4 0.124 M4	Grid 5 0.157 M3	Grid 6 0.157 M3
Grid 7 0.133 M4	Grid 8 0.153 M3	Grid 9 0.154 M3



0 dB = 0.169A/m

Figure 22 HAC RF H-Field GSM 1900 Channel 661

TA Technology (Shanghai) Co., Ltd. Test Report

HAC RF H-Field GSM 1900 Low

Date/Time: 6/30/2011 7:30:04 PM

Communication System: PCS 1900; Frequency: 1850.2 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

H Scan - H3DV6 - 2007: 15 mm from Probe Low/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.169 A/m

Probe Modulation Factor = 2.84

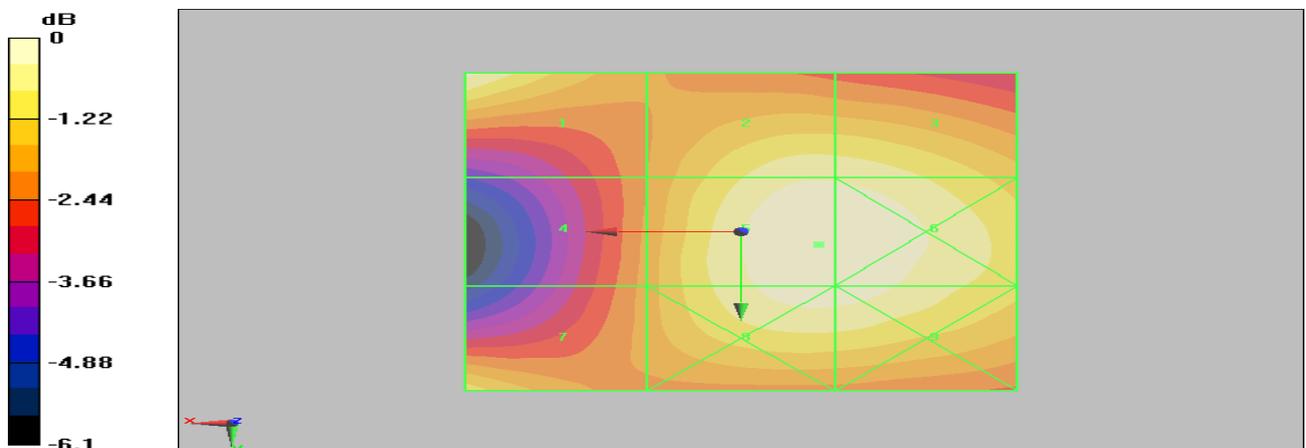
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.067 A/m; Power Drift = 0.000 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak H-field in A/m

Grid 1 0.165 M3	Grid 2 0.161 M3	Grid 3 0.160 M3
Grid 4 0.137 M4	Grid 5 0.169 M3	Grid 6 0.169 M3
Grid 7 0.152 M3	Grid 8 0.166 M3	Grid 9 0.166 M3



0 dB = 0.169A/m

Figure 23 HAC RF H-Field GSM 1900 Channel 512

TA Technology (Shanghai) Co., Ltd. Test Report

HAC RF E-Field WCDMA Band II High

Date/Time: 6/30/2011 10:07:40 PM

Communication System: WCDMA Band II; Frequency: 1907.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device High/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 27.9 V/m

Probe Modulation Factor = 1.02

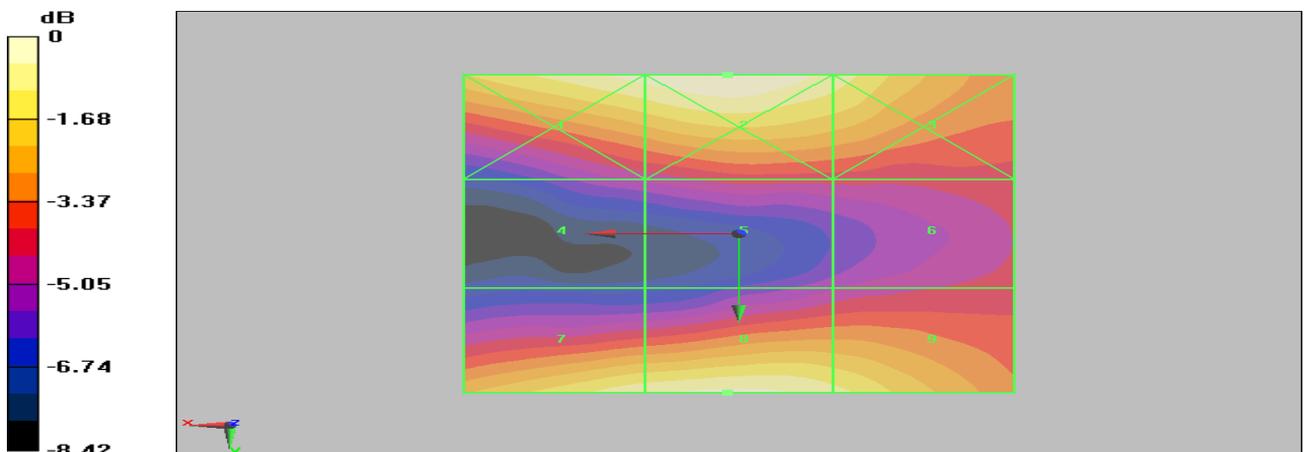
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 11.6 V/m; Power Drift = 0.016 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 28.1 M4	Grid 2 29.1 M4	Grid 3 26.6 M4
Grid 4 16.6 M4	Grid 5 18 M4	Grid 6 18.2 M4
Grid 7 27 M4	Grid 8 27.9 M4	Grid 9 26.3 M4



0 dB = 29.1V/m

Figure 24 HAC RF E-Field WCDMA Band II Channel 9538

TA Technology (Shanghai) Co., Ltd. Test Report

HAC RF E-Field WCDMA Band II Middle

Date/Time: 6/30/2011 10:02:17 PM

Communication System: WCDMA Band II; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Middle/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 24.9 V/m

Probe Modulation Factor = 1.02

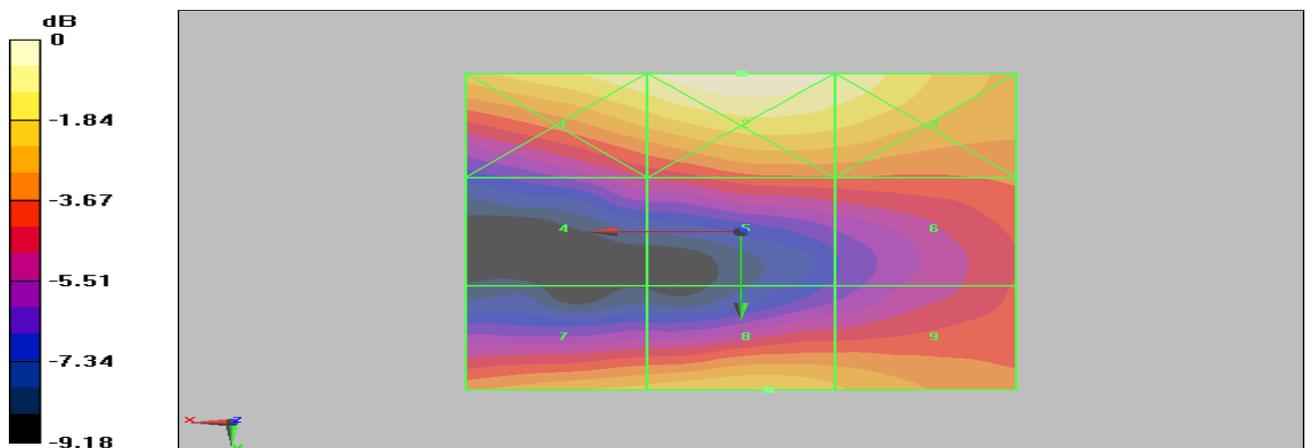
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 13.1 V/m; Power Drift = 0.134 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 28.3 M4	Grid 2 30.5 M4	Grid 3 28.5 M4
Grid 4 17.5 M4	Grid 5 19.9 M4	Grid 6 20.4 M4
Grid 7 23.9 M4	Grid 8 24.9 M4	Grid 9 23.4 M4



0 dB = 30.5V/m

Figure 25 HAC RF E-Field WCDMA Band II Channel 9400

HAC RF E-Field WCDMA Band II Low

Date/Time: 6/30/2011 10:13:00 PM

Communication System: WCDMA Band II; Frequency: 1852.4 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Low/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 28 V/m

Probe Modulation Factor = 1.02

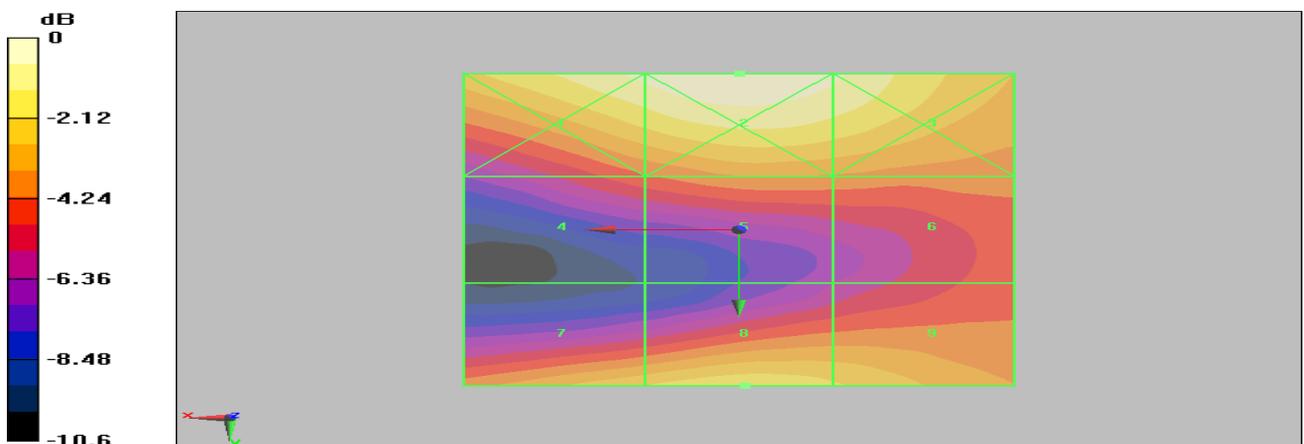
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 15.9 V/m; Power Drift = 0.051 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 31.4 M4	Grid 2 33.3 M4	Grid 3 31.3 M4
Grid 4 20.2 M4	Grid 5 22.3 M4	Grid 6 22 M4
Grid 7 26.2 M4	Grid 8 28 M4	Grid 9 26.5 M4



0 dB = 33.3V/m

Figure 26 HAC RF E-Field WCDMA Band II Channel 9262

HAC RF E-Field WCDMA Band II HSDPA High

Date/Time: 6/30/2011 9:50:24 PM

Communication System: WCDMA Band II+HSDPA; Frequency: 1907.6 MHz;Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature:22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device High/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 26.6 V/m

Probe Modulation Factor = 1.02

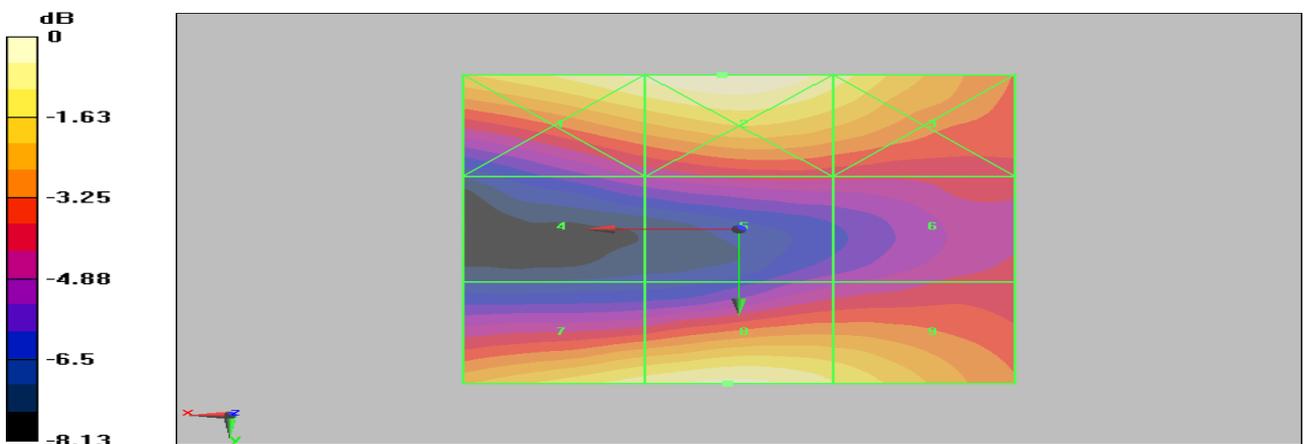
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 11.1 V/m; Power Drift = 0.140 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
26.7 M4	27.7 M4	25.3 M4
Grid 4	Grid 5	Grid 6
15.9 M4	17.3 M4	17.5 M4
Grid 7	Grid 8	Grid 9
25.4 M4	26.6 M4	24.6 M4



0 dB = 27.7V/m

Figure 27 HAC RF E-Field WCDMA Band II HSDPA Channel 9538

HAC RF E-Field WCDMA Band II HSDPA Middle

Date/Time: 6/30/2011 9:44:54 PM

Communication System: WCDMA Band II+HSDPA; Frequency: 1880 MHz;Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature:22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Middle/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 25 V/m

Probe Modulation Factor = 1.02

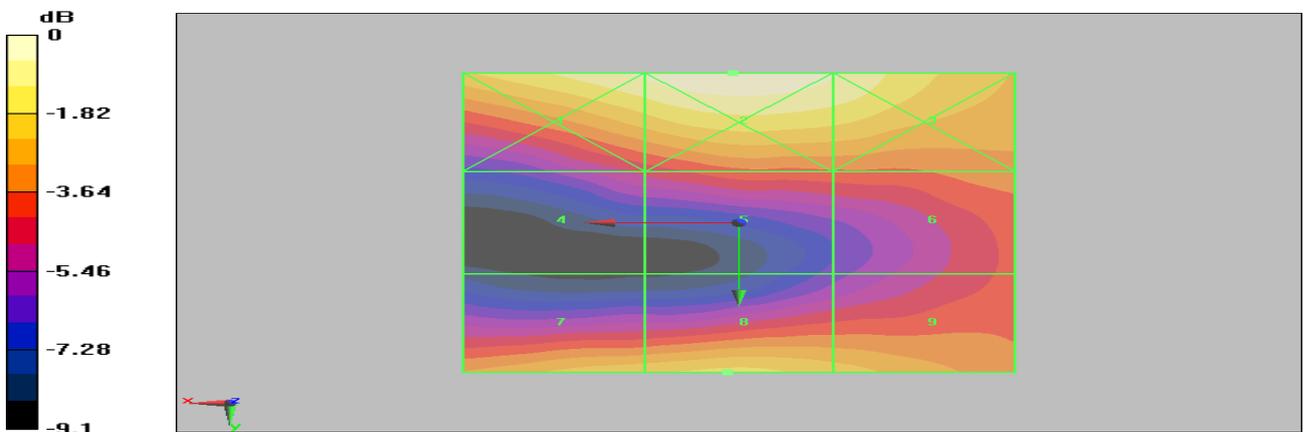
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 13.1 V/m; Power Drift = -0.010 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
28.5 M4	29.9 M4	28.2 M4
Grid 4	Grid 5	Grid 6
17.5 M4	19.5 M4	20.4 M4
Grid 7	Grid 8	Grid 9
24.2 M4	25 M4	23.7 M4



0 dB = 29.9V/m

Figure 28 HAC RF E-Field WCDMA Band II HSDPA Channel 9400

TA Technology (Shanghai) Co., Ltd. Test Report

HAC RF E-Field WCDMA Band II HSDPA Low

Date/Time: 6/30/2011 9:55:55 PM

Communication System: WCDMA Band II+HSDPA; Frequency: 1852.4 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Low/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 26.3 V/m

Probe Modulation Factor = 1.02

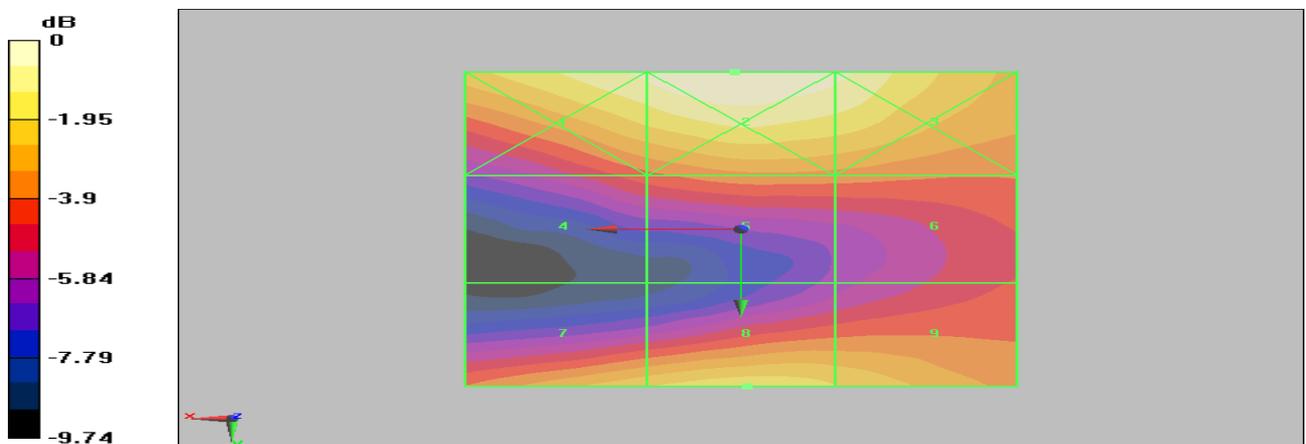
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 15.3 V/m; Power Drift = -0.060 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 29.3 M4	Grid 2 30.9 M4	Grid 3 29.3 M4
Grid 4 19.2 M4	Grid 5 20.9 M4	Grid 6 20.6 M4
Grid 7 24.6 M4	Grid 8 26.3 M4	Grid 9 24.9 M4



0 dB = 30.9V/m

Figure 29 HAC RF E-Field WCDMA Band II HSDPA Channel 9262

TA Technology (Shanghai) Co., Ltd. Test Report

HAC RF H-Field WCDMA Band II High

Date/Time: 6/30/2011 8:04:46 PM

Communication System: WCDMA Band II; Frequency: 1907.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

H Scan - H3DV6 - 2007: 15 mm from Probe High/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.071 A/m

Probe Modulation Factor = 1.01

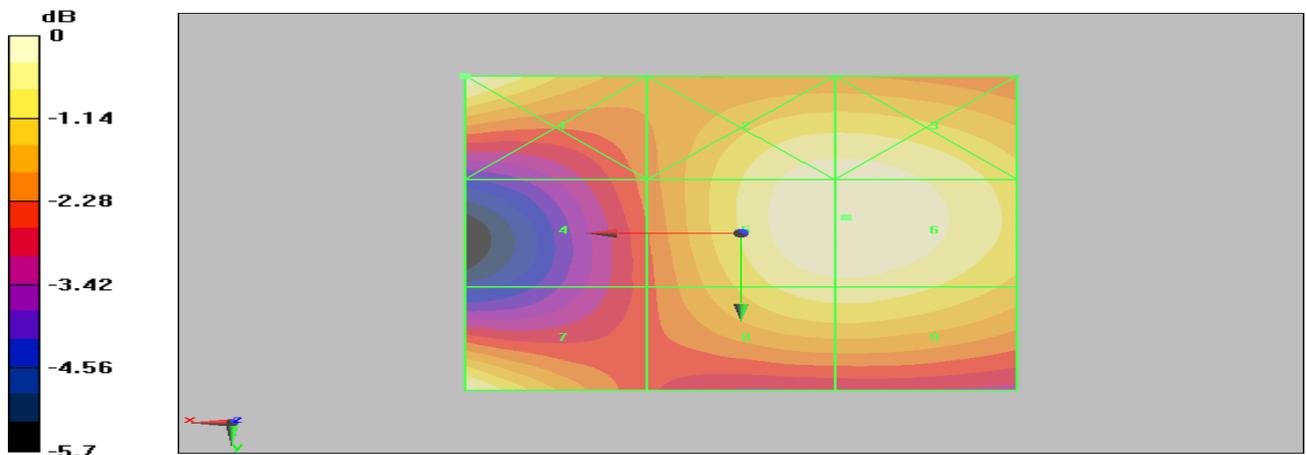
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.076 A/m; Power Drift = -0.018 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.071 M4	0.070 M4	0.070 M4
Grid 4	Grid 5	Grid 6
0.056 M4	0.071 M4	0.071 M4
Grid 7	Grid 8	Grid 9
0.070 M4	0.067 M4	0.067 M4



0 dB = 0.071A/m

Figure 30 HAC RF H-Field WCDMA Band II Channel 9538

HAC RF H-Field WCDMA Band II Middle

Date/Time: 6/30/2011 7:59:21 PM

Communication System: WCDMA Band II; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

H Scan - H3DV6 - 2007: 15 mm from Probe Middle/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.071 A/m

Probe Modulation Factor = 1.01

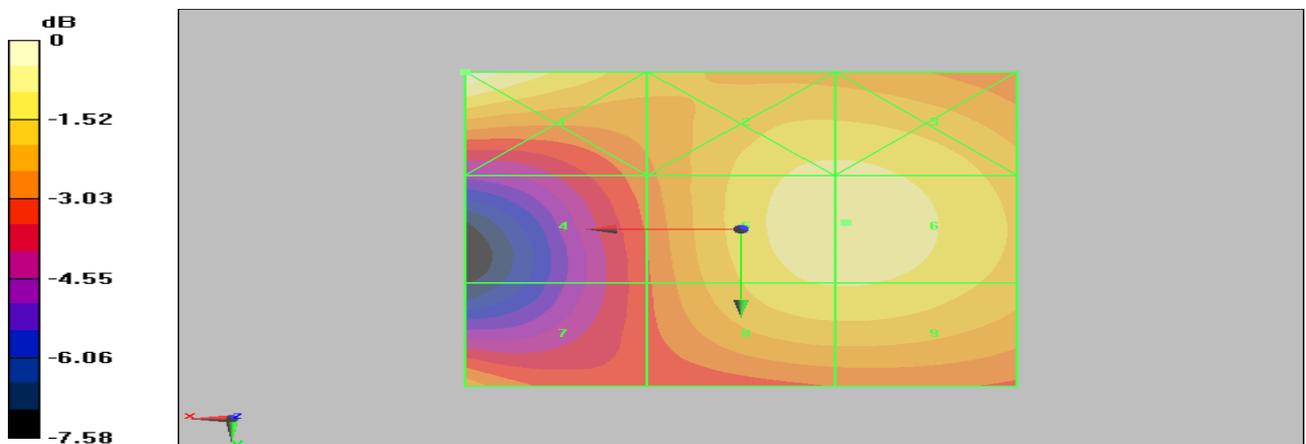
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.078 A/m; Power Drift = -0.080 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.077 M4	Grid 2 0.070 M4	Grid 3 0.070 M4
Grid 4 0.057 M4	Grid 5 0.071 M4	Grid 6 0.071 M4
Grid 7 0.060 M4	Grid 8 0.069 M4	Grid 9 0.069 M4



0 dB = 0.077A/m

Figure 31 HAC RF H-Field WCDMA Band II Channel 9400

TA Technology (Shanghai) Co., Ltd. Test Report

HAC RF H-Field WCDMA Band II Low

Date/Time: 6/30/2011 8:10:13 PM

Communication System: WCDMA Band II; Frequency: 1852.4 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

H Scan - H3DV6 - 2007: 15 mm from Probe Low/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.078 A/m

Probe Modulation Factor = 1.01

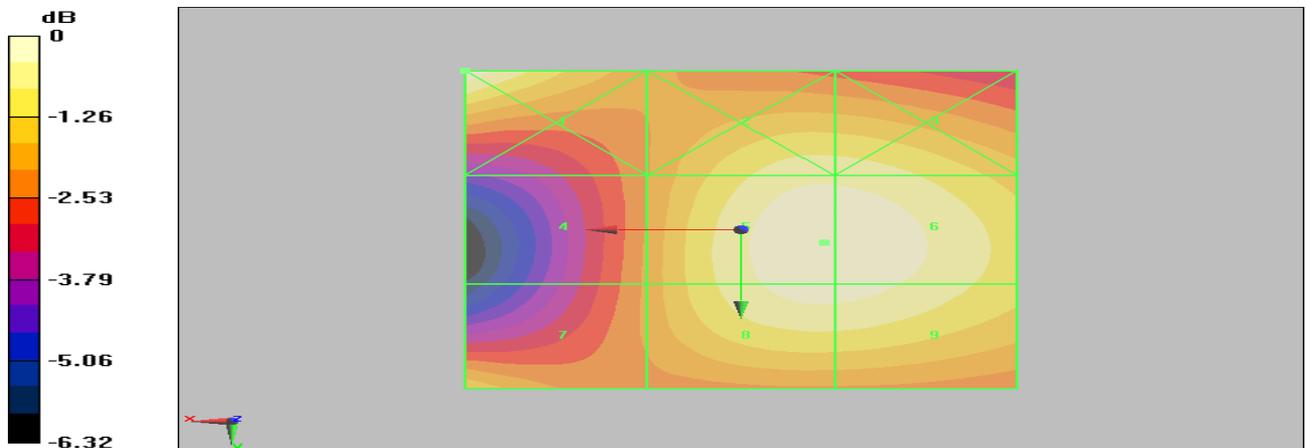
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.087 A/m; Power Drift = -0.035 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.078 M4	0.073 M4	0.073 M4
Grid 4	Grid 5	Grid 6
0.062 M4	0.078 M4	0.077 M4
Grid 7	Grid 8	Grid 9
0.068 M4	0.076 M4	0.076 M4



0 dB = 0.078A/m

Figure 32 HAC RF H-Field WCDMA Band II Channel 9262

TA Technology (Shanghai) Co., Ltd. Test Report

HAC RF H-Field WCDMA Band II HSDPA High

Date/Time: 6/30/2011 7:47:43 PM

Communication System: WCDMA Band II+HSDPA; Frequency: 1907.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

H Scan - H3DV6 - 2007: 15 mm from Probe High/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.067 A/m

Probe Modulation Factor = 1.01

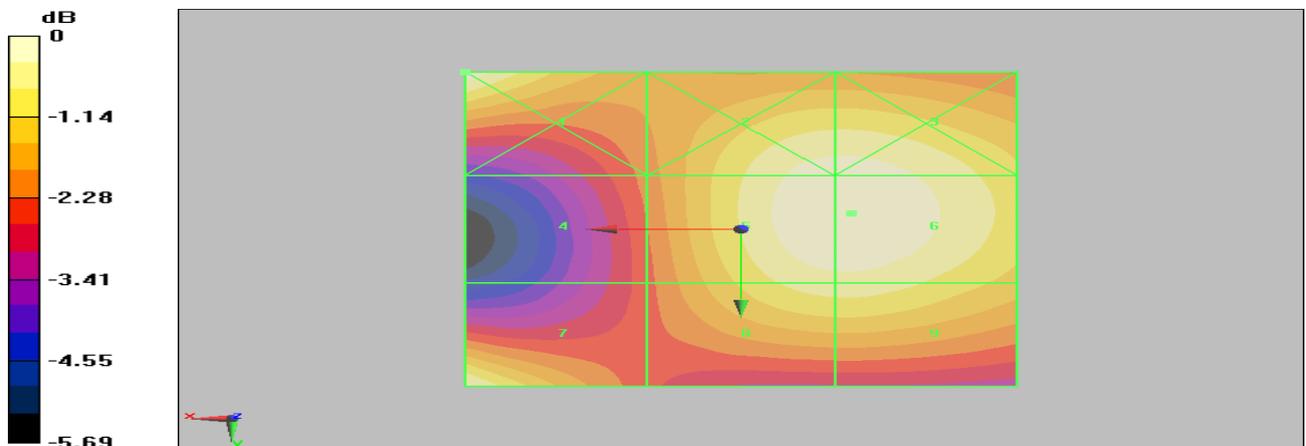
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.071 A/m; Power Drift = -0.002 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.067 M4	0.066 M4	0.066 M4
Grid 4	Grid 5	Grid 6
0.053 M4	0.067 M4	0.067 M4
Grid 7	Grid 8	Grid 9
0.065 M4	0.063 M4	0.063 M4



0 dB = 0.067A/m

Figure 33 HAC RF H-Field WCDMA Band II HSDPA Channel 9538

HAC RF H-Field WCDMA Band II HSDPA Middle

Date/Time: 6/30/2011 7:42:17 PM

Communication System: WCDMA Band II+HSDPA; Frequency: 1880 MHz;Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature:22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

H Scan - H3DV6 - 2007: 15 mm from Probe Middle/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.067 A/m

Probe Modulation Factor = 1.01

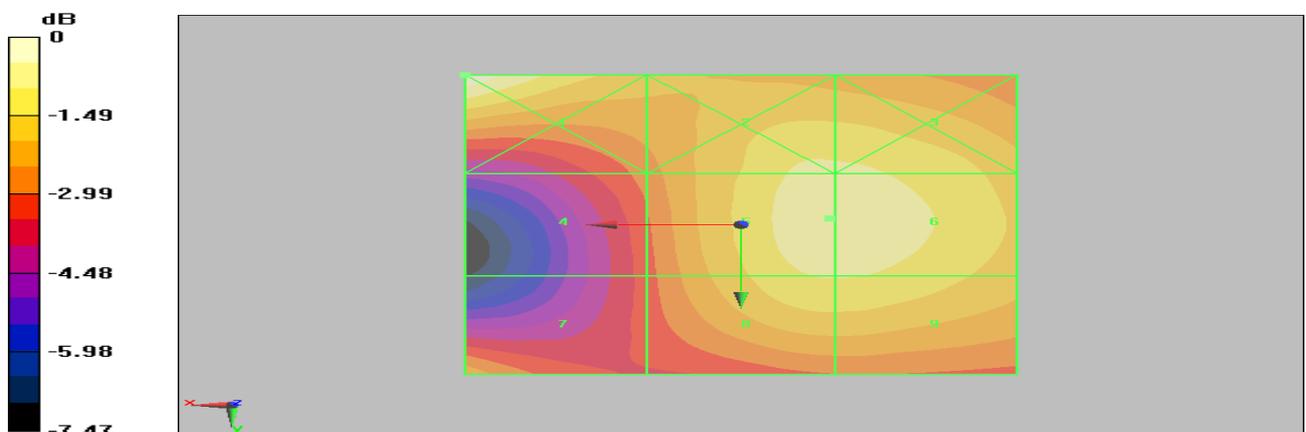
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.072 A/m; Power Drift = -0.040 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.072 M4	Grid 2 0.065 M4	Grid 3 0.065 M4
Grid 4 0.053 M4	Grid 5 0.067 M4	Grid 6 0.066 M4
Grid 7 0.057 M4	Grid 8 0.064 M4	Grid 9 0.064 M4



0 dB = 0.072A/m

Figure 34 HAC RF H-Field WCDMA Band II HSDPA Channel 9400

TA Technology (Shanghai) Co., Ltd. Test Report

HAC RF H-Field WCDMA Band II HSDPA Low

Date/Time: 6/30/2011 7:53:07 PM

Communication System: WCDMA Band II+HSDPA; Frequency: 1852.4 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

H Scan - H3DV6 - 2007: 15 mm from Probe Low/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.072 A/m

Probe Modulation Factor = 1.01

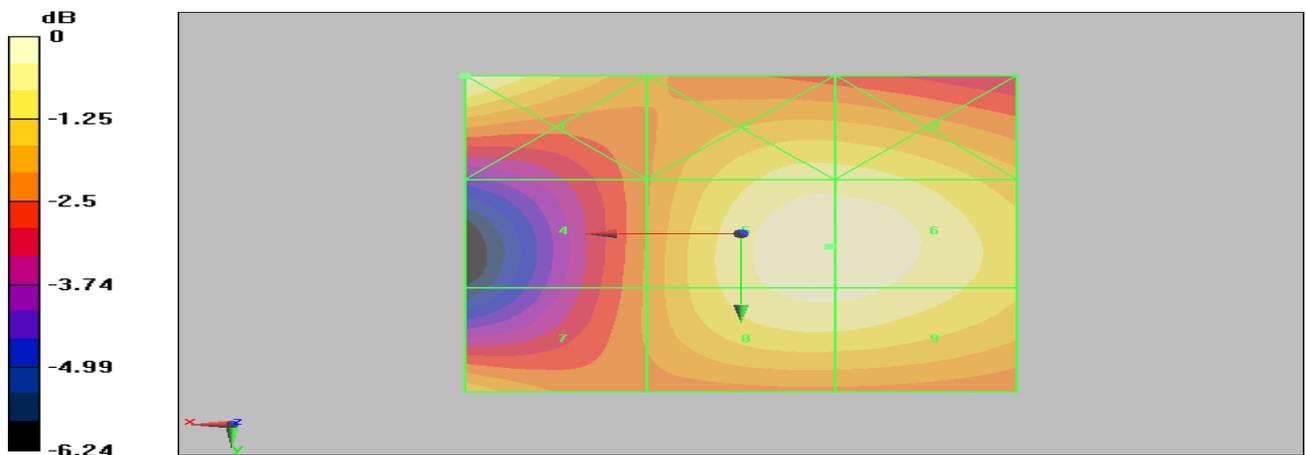
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.080 A/m; Power Drift = 0.006 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.073 M4	0.068 M4	0.068 M4
Grid 4	Grid 5	Grid 6
0.058 M4	0.072 M4	0.072 M4
Grid 7	Grid 8	Grid 9
0.063 M4	0.071 M4	0.071 M4



0 dB = 0.073A/m

Figure 35 HAC RF H-Field WCDMA Band II HSDPA Channel 9262

HAC RF E-Field WCDMA Band V High

Date/Time: 6/30/2011 10:43:19 PM

Communication System: WCDMA Band V; Frequency: 846.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device High/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 62.9 V/m

Probe Modulation Factor = 1.03

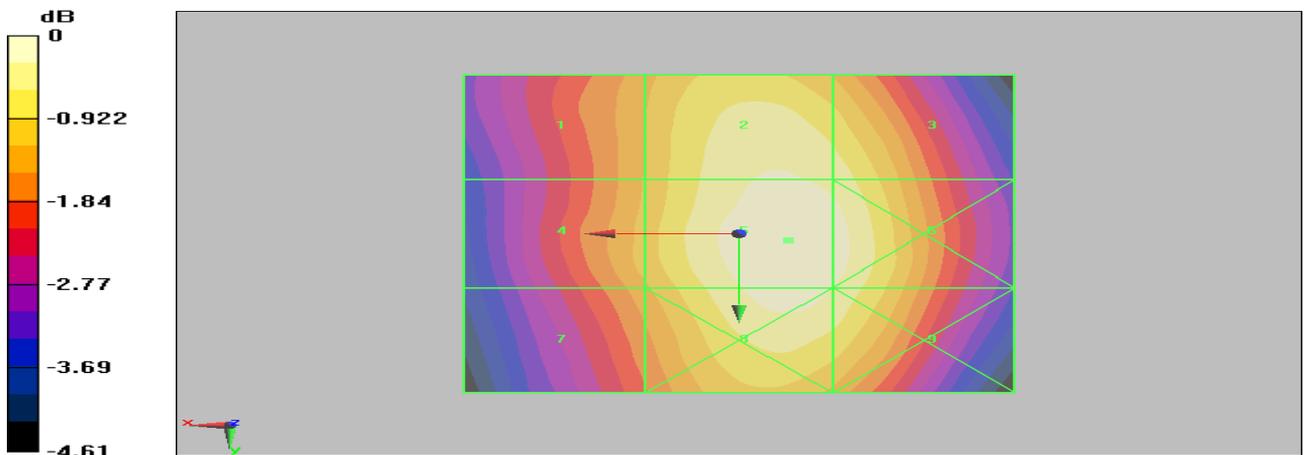
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 79.3 V/m; Power Drift = -0.038 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
54.8 M4	61 M4	60 M4
Grid 4	Grid 5	Grid 6
55.6 M4	62.9 M4	61.8 M4
Grid 7	Grid 8	Grid 9
54.2 M4	62 M4	60.7 M4



0 dB = 62.9V/m

Figure 36 HAC RF E-Field WCDMA Band V Channel 4233

HAC RF E-Field WCDMA Band V Middle

Date/Time: 6/30/2011 10:37:44 PM

Communication System: WCDMA Band V; Frequency: 836.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Middle/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 69.2 V/m

Probe Modulation Factor = 1.03

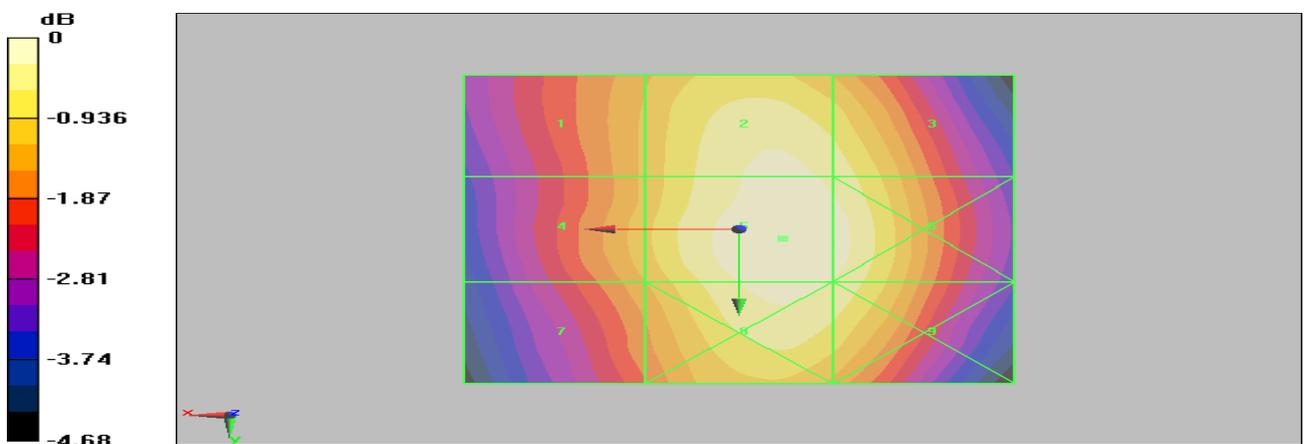
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 87.7 V/m; Power Drift = 0.021 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
60.6 M4	67.5 M4	66.1 M4
Grid 4	Grid 5	Grid 6
61.5 M4	69.2 M4	68 M4
Grid 7	Grid 8	Grid 9
59.9 M4	67.8 M4	66.7 M4



0 dB = 69.2V/m

Figure 37 HAC RF E-Field WCDMA Band V Channel 4183

TA Technology (Shanghai) Co., Ltd. Test Report

HAC RF E-Field WCDMA Band V Low

Date/Time: 6/30/2011 10:48:51 PM

Communication System: WCDMA Band V; Frequency: 826.4 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Low/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 58.1 V/m

Probe Modulation Factor = 1.03

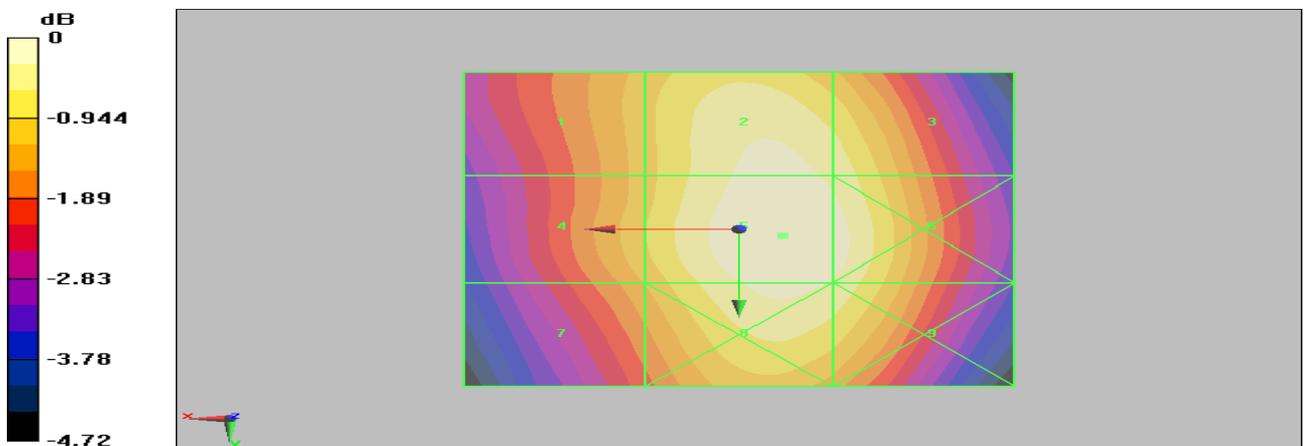
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 73 V/m; Power Drift = 0.058 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
51.6 M4	56.8 M4	55.6 M4
Grid 4	Grid 5	Grid 6
52.1 M4	58.1 M4	57 M4
Grid 7	Grid 8	Grid 9
50.4 M4	56.8 M4	55.8 M4



0 dB = 58.1V/m

Figure 38 HAC RF E-Field WCDMA Band V Channel 4132

HAC RF E-Field WCDMA Band V HSDPA High

Date/Time: 6/30/2011 10:26:24 PM

Communication System: WCDMA Band V+HSDPA; Frequency: 846.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device High/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 63.3 V/m

Probe Modulation Factor = 1.03

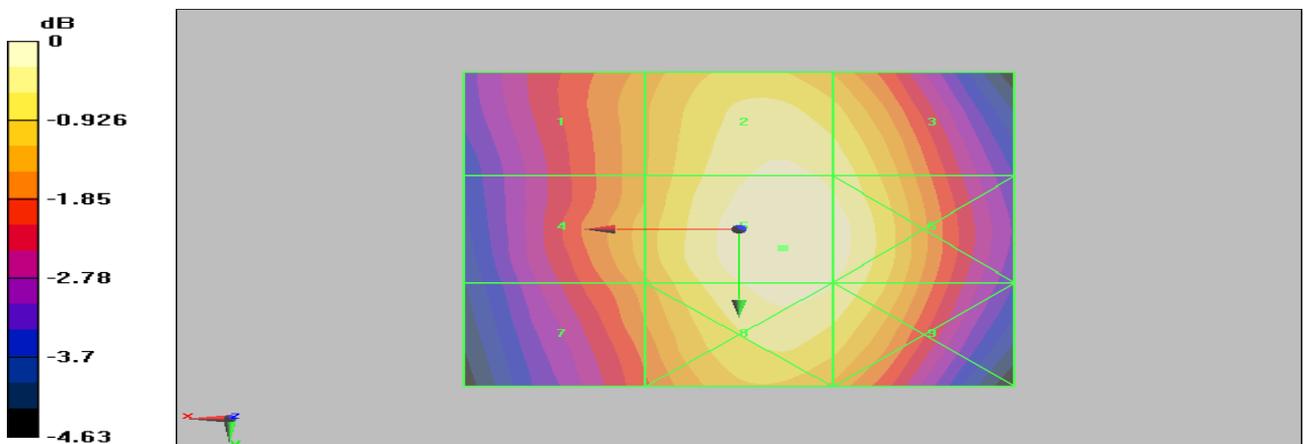
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 79.4 V/m; Power Drift = -0.025 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
54.8 M4	61.6 M4	60.5 M4
Grid 4	Grid 5	Grid 6
56 M4	63.3 M4	62.3 M4
Grid 7	Grid 8	Grid 9
54.4 M4	62.2 M4	61.2 M4



0 dB = 63.3V/m

Figure 39 HAC RF E-Field WCDMA Band V HSDPA Channel 4233

TA Technology (Shanghai) Co., Ltd. Test Report

HAC RF E-Field WCDMA Band V HSDPA Middle

Date/Time: 6/30/2011 10:21:08 PM

Communication System: WCDMA Band V+HSDPA; Frequency: 836.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Middle/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 66.9 V/m

Probe Modulation Factor = 1.03

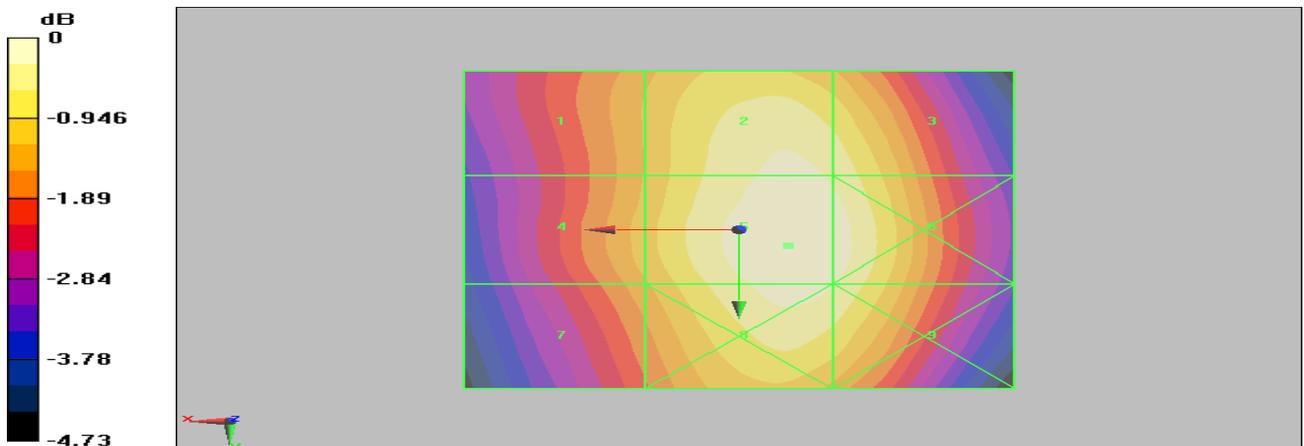
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 83.9 V/m; Power Drift = 0.048 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 58.1 M4	Grid 2 65.3 M4	Grid 3 64.1 M4
Grid 4 59.1 M4	Grid 5 66.9 M4	Grid 6 65.9 M4
Grid 7 57.6 M4	Grid 8 65.7 M4	Grid 9 64.6 M4



0 dB = 66.9V/m

Figure 40 HAC RF E-Field WCDMA Band V HSDPA Channel 4183

HAC RF E-Field WCDMA Band V HSDPA Low

Date/Time: 6/30/2011 10:32:05 PM

Communication System: WCDMA Band V+HSDPA; Frequency: 826.4 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Low/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 57 V/m

Probe Modulation Factor = 1.03

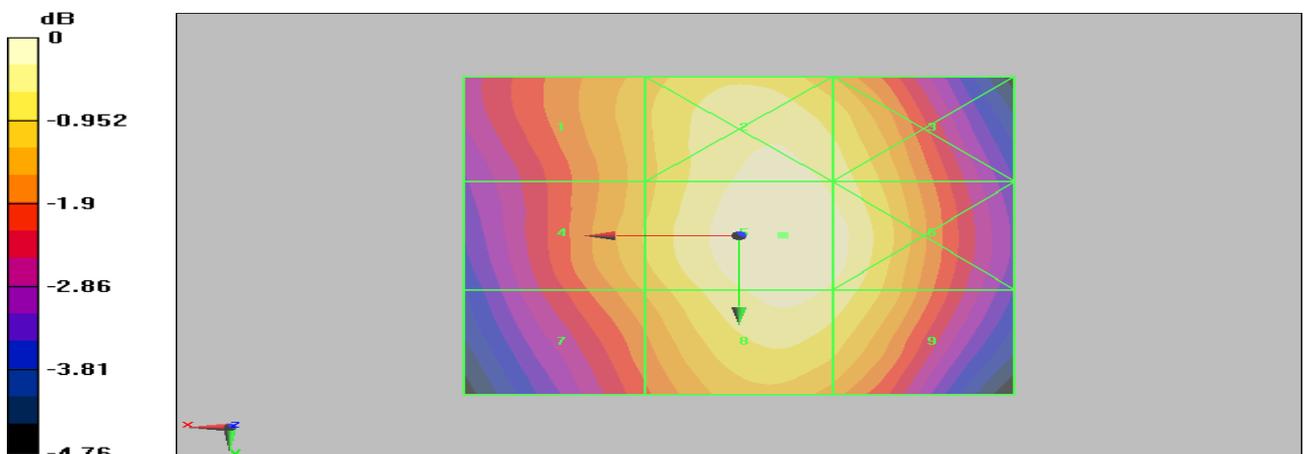
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 72 V/m; Power Drift = -0.047 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
50.8 M4	55.9 M4	54.4 M4
Grid 4	Grid 5	Grid 6
51.3 M4	57 M4	55.9 M4
Grid 7	Grid 8	Grid 9
49.6 M4	55.7 M4	54.6 M4



0 dB = 57V/m

Figure 41 HAC RF E-Field WCDMA Band V HSDPA Channel 4132

HAC RF H-Field WCDMA Band V High

Date/Time: 6/30/2011 8:43:18 PM

Communication System: WCDMA Band V; Frequency: 846.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

H Scan - H3DV6 - 2007: 15 mm from Probe High/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.092 A/m

Probe Modulation Factor = 1.01

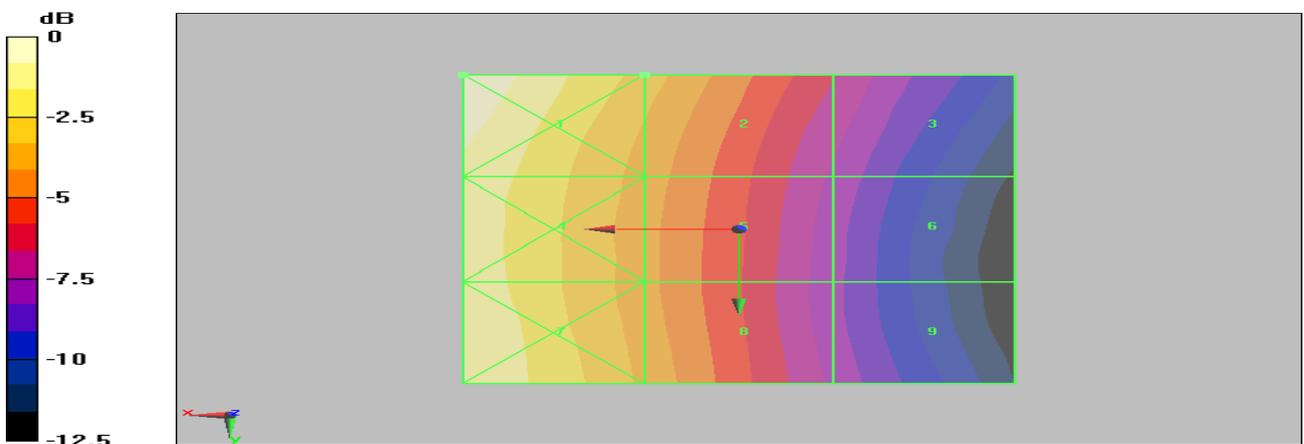
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.068 A/m; Power Drift = -0.003 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.128 M4	Grid 2 0.092 M4	Grid 3 0.060 M4
Grid 4 0.114 M4	Grid 5 0.084 M4	Grid 6 0.053 M4
Grid 7 0.117 M4	Grid 8 0.085 M4	Grid 9 0.053 M4



0 dB = 0.128A/m

Figure 42 HAC RF H-Field WCDMA Band V Channel 4233

HAC RF H-Field WCDMA Band V Middle

Date/Time: 6/30/2011 8:37:54 PM

Communication System: WCDMA Band V; Frequency: 836.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

H Scan - H3DV6 - 2007: 15 mm from Probe Middle/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.104 A/m

Probe Modulation Factor = 1.01

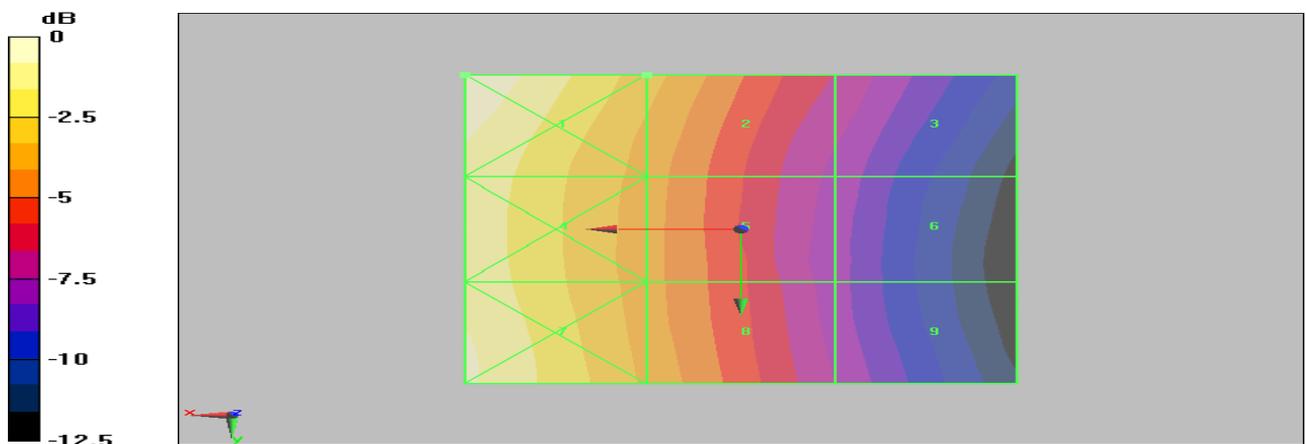
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.078 A/m; Power Drift = 0.009 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.146 M4	Grid 2 0.104 M4	Grid 3 0.068 M4
Grid 4 0.129 M4	Grid 5 0.095 M4	Grid 6 0.060 M4
Grid 7 0.135 M4	Grid 8 0.098 M4	Grid 9 0.062 M4



0 dB = 0.146A/m

Figure 43 HAC RF H-Field WCDMA Band V Channel 4183

HAC RF H-Field WCDMA Band V Low

Date/Time: 6/30/2011 8:48:57 PM

Communication System: WCDMA Band V; Frequency: 826.4 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

H Scan - H3DV6 - 2007: 15 mm from Probe Low/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.086 A/m

Probe Modulation Factor = 1.01

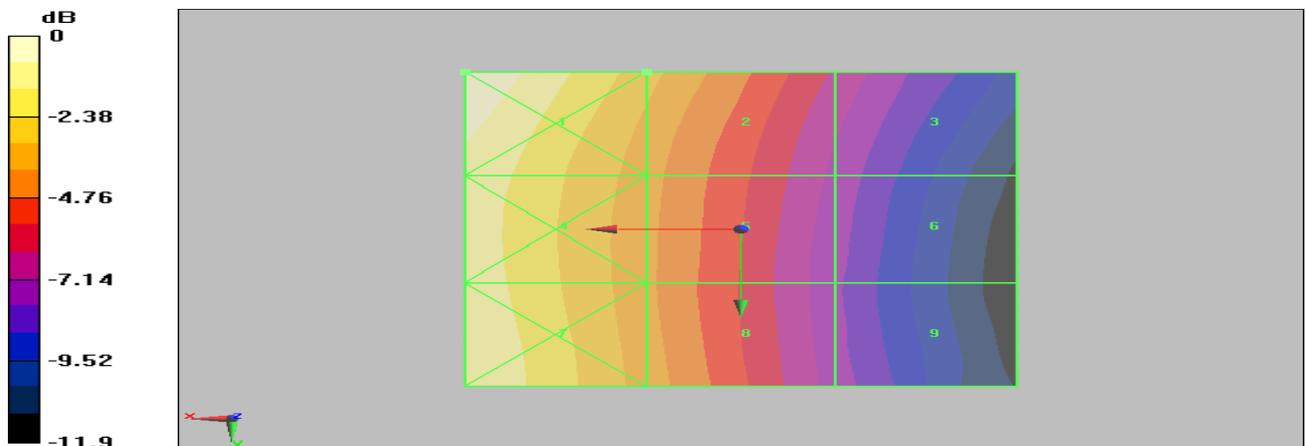
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.065 A/m; Power Drift = 0.068 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.119 M4	Grid 2 0.086 M4	Grid 3 0.057 M4
Grid 4 0.106 M4	Grid 5 0.078 M4	Grid 6 0.051 M4
Grid 7 0.109 M4	Grid 8 0.079 M4	Grid 9 0.051 M4



0 dB = 0.119A/m

Figure 44 HAC RF H-Field WCDMA Band V Channel 4132

HAC RF H-Field WCDMA Band V HSDPA High

Date/Time: 6/30/2011 8:26:49 PM

Communication System: WCDMA Band V+HSDPA; Frequency: 846.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

H Scan - H3DV6 - 2007: 15 mm from Probe High/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.091 A/m

Probe Modulation Factor = 1.01

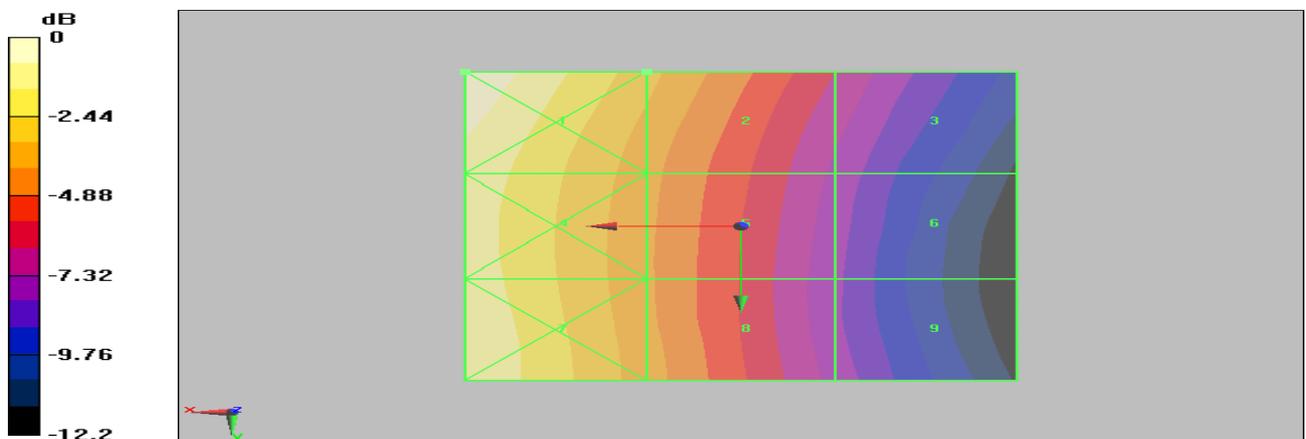
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.068 A/m; Power Drift = -0.023 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.127 M4	Grid 2 0.091 M4	Grid 3 0.060 M4
Grid 4 0.112 M4	Grid 5 0.082 M4	Grid 6 0.054 M4
Grid 7 0.115 M4	Grid 8 0.083 M4	Grid 9 0.053 M4



0 dB = 0.127A/m

Figure 45 HAC RF H-Field WCDMA Band V HSDPA Channel 4233

HAC RF H-Field WCDMA Band V HSDPA Middle

Date/Time: 6/30/2011 8:21:29 PM

Communication System: WCDMA Band V+HSDPA; Frequency: 836.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

H Scan - H3DV6 - 2007: 15 mm from Probe Middle/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.098 A/m

Probe Modulation Factor = 1.01

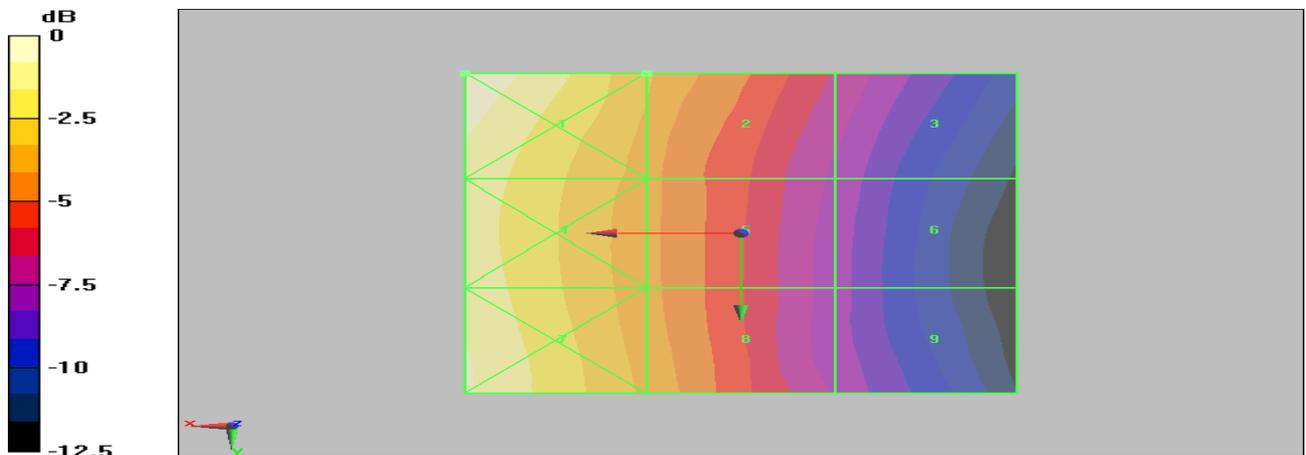
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.076 A/m; Power Drift = -0.030 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.141 M4	Grid 2 0.098 M4	Grid 3 0.065 M4
Grid 4 0.124 M4	Grid 5 0.091 M4	Grid 6 0.058 M4
Grid 7 0.130 M4	Grid 8 0.094 M4	Grid 9 0.059 M4



0 dB = 0.141A/m

Figure 46 HAC RF H-Field WCDMA Band V HSDPA Channel 4183

HAC RF H-Field WCDMA Band V HSDPA Low

Date/Time: 6/30/2011 8:32:14 PM

Communication System: WCDMA Band V+HSDPA; Frequency: 826.4 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 22.3 °C

Phantom section: RF Section

DASY5 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/18/2010

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY5, V5.0 Build 120; SEMCAD X Version 13.4 Build 45

H Scan - H3DV6 - 2007: 15 mm from Probe Low/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.084 A/m

Probe Modulation Factor = 1.01

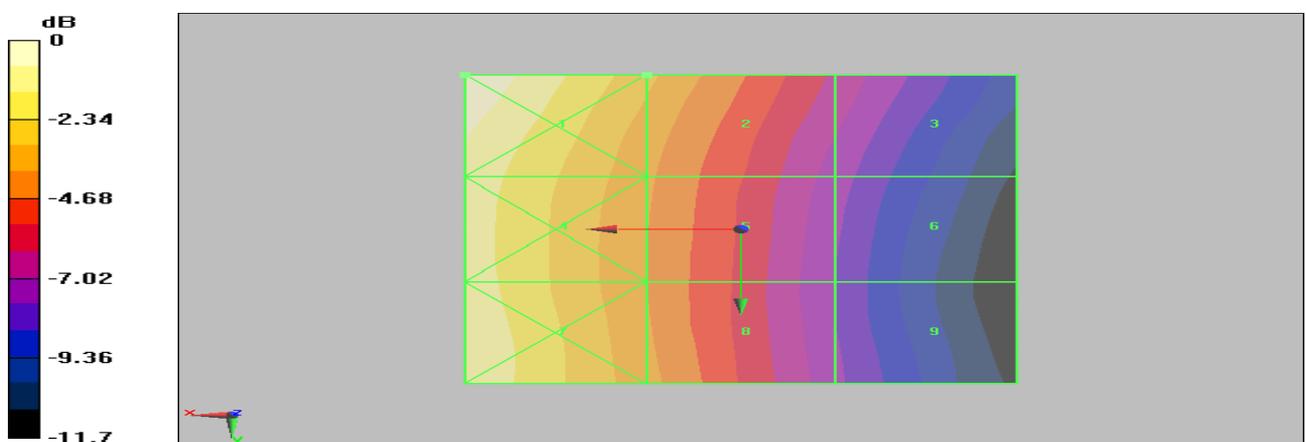
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.063 A/m; Power Drift = 0.055 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.117 M4	Grid 2 0.084 M4	Grid 3 0.056 M4
Grid 4 0.103 M4	Grid 5 0.076 M4	Grid 6 0.050 M4
Grid 7 0.106 M4	Grid 8 0.077 M4	Grid 9 0.049 M4



0 dB = 0.117A/m

Figure 47 HAC RF H-Field WCDMA Band V HSDPA Channel 4132

TA Technology (Shanghai) Co., Ltd. Test Report

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ANNEX C: E-Probe Calibration Certificate

**Calibration Laboratory of
Schmid & Partner
Engineering AG**
Zeughausstrasse 43, 8004 Zurich, Switzerland



S Schweizerischer Kalibrierdienst
C Service suisse d'étalonnage
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Accreditation No.: **SCS 108**

Client **TMC**

Certificate No: **ER3-2428_Oct09**

CALIBRATION CERTIFICATE

Object **ER3DV6 - SN:2428**

Calibration procedure(s) **QA CAL-02.v5 and QA CAL-25.v2
Calibration procedure for E-field probes optimized for close near field
evaluations in air**

Calibration date: **October 20, 2009**

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).
The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration):

Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration
Power meter E4418B	GB41283874	1-Apr-09 (No. 217-01030)	Apr-10
Power sensor E4412A	MY41495277	1-Apr-09 (No. 217-01030)	Apr-10
Power sensor E4412A	MY41498087	1-Apr-09 (No. 217-01030)	Apr-10
Reference 3 dB Attenuator	SN: S5054 (3c)	31-Mar-09 (No. 217-01026)	Mar-10
Reference 20 dB Attenuator	SN: S5086 (20b)	31-Mar-09 (No. 217-01026)	Mar-10
Reference 30 dB Attenuator	SN: S5129 (30b)	31-Mar-09 (No. 217-01027)	Mar-10
Reference Probe ER3DV6	SN: 2328	3-Oct-09 (No. ER3-2328_Oct09)	Oct-10
DAE4	SN: 789	19-Dec-08 (No. DAE4-789_Dec08)	Dec-09
Secondary Standards	ID #	Check Date (in house)	Scheduled Check
RF generator HP 8648C	US3642U01700	4-Aug-09 (in house check Oct-09)	In house check: Oct-11
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-09)	In house check: Oct10

Calibrated by:	Name	Function	Signature
	Marcel Fehr	Laboratory Technician	
Approved by:	Name	Function	Signature
	Katja Pokovic	Technical Manager	

Issued: October 22, 2009

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Certificate No: ER3-2428_Oct09

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TA Technology (Shanghai) Co., Ltd.

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Report No. RZA1106-1087HAC01R1

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Calibration Laboratory of
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Accreditation No.: **SCS 108**

Glossary:

NORM _{x,y,z}	sensitivity in free space
DCP	diode compression point
CF	crest factor (1/duty_cycle) of the RF signal
A, B, C	modulation dependent linearization parameters
Polarization φ	φ rotation around probe axis
Polarization ϑ	ϑ rotation around an axis that is in the plane normal to probe axis (at measurement center), i.e., $\vartheta = 0$ is normal to probe axis
Connector Angle	information used in DASY system to align probe sensor X to the robot coordinate system

Calibration is Performed According to the Following Standards:

- IEEE Std 1309-2005, "IEEE Standard for calibration of electromagnetic field sensors and probes, excluding antennas, from 9 kHz to 40 GHz", December 2005.

Methods Applied and Interpretation of Parameters:

- NORM_{x,y,z}*: Assessed for E-field polarization $\vartheta = 0$ for XY sensors and $\vartheta = 90$ for Z sensor ($f \leq 900$ MHz in TEM-cell; $f > 1800$ MHz: R22 waveguide).
- NORM(f)_{x,y,z}* = *NORM_{x,y,z}* * *frequency_response* (see Frequency Response Chart).
- DCP_{x,y,z}*: DCP are numerical linearization parameters assessed based on the data of power sweep with CW signal (no uncertainty required). DCP does not depend on frequency nor media.
- A_{x,y,z}*; *B_{x,y,z}*; *C_{x,y,z}* are numerical linearization parameters assessed based on the data of power sweep for specific modulation signal. The parameters do not depend on frequency nor media.
- Spherical isotropy (3D deviation from isotropy)*: in a locally homogeneous field realized using an open waveguide setup.
- Sensor Offset*: The sensor offset corresponds to the offset of virtual measurement center from the probe tip (on probe axis). No tolerance required.
- Connector Angle*: The angle is assessed using the information gained by determining the *NORM_x* (no uncertainty required).

ER3DV6 SN:2428

October 20, 2009

Probe ER3DV6

SN:2428

Manufactured:	September 11, 2007
Last calibrated:	December 13, 2007
Recalibrated:	October 20, 2009

Calibrated for DASY Systems

(Note: non-compatible with DASY2 system!)

TA Technology (Shanghai) Co., Ltd. Test Report

ER3DV6 SN:2428

October 20, 2009

DASY - Parameters of Probe: ER3DV6 SN:2428

Basic Calibration Parameters

	Sensor X	Sensor Y	Sensor Z	Unc (k=2)
Norm ($\mu\text{V}/(\text{V}/\text{m})^2$)	1.52	1.59	1.86	$\pm 10.1\%$
DCP (mV) [^]	91.5	93.0	98.9	

Modulation Calibration Parameters

UID	Communication System Name	PAR		A dB	B dBuV	C	VR mV	Unc (k=2)
10000	CW		X	0.00	0.00	1.00	300	$\pm 1.5\%$
			Y	0.00	0.00	1.00	300	
			Z	0.00	0.00	1.00	300	

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor $k=2$, which for a normal distribution corresponds to a coverage probability of approximately 95%.

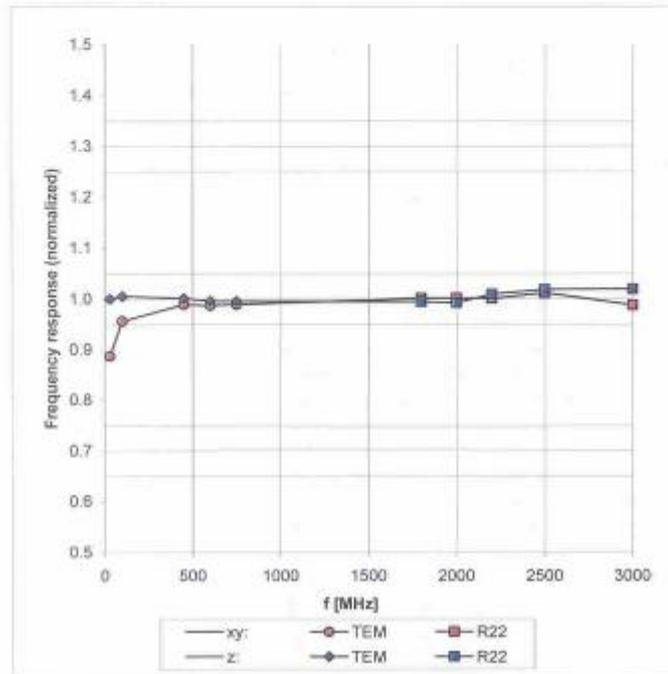
[^] numerical linearization parameter: uncertainty not required

ER3DV6 SN:2428

October 20, 2009

Frequency Response of E-Field

(TEM-Cell:ifi110 EXX, Waveguide R22)

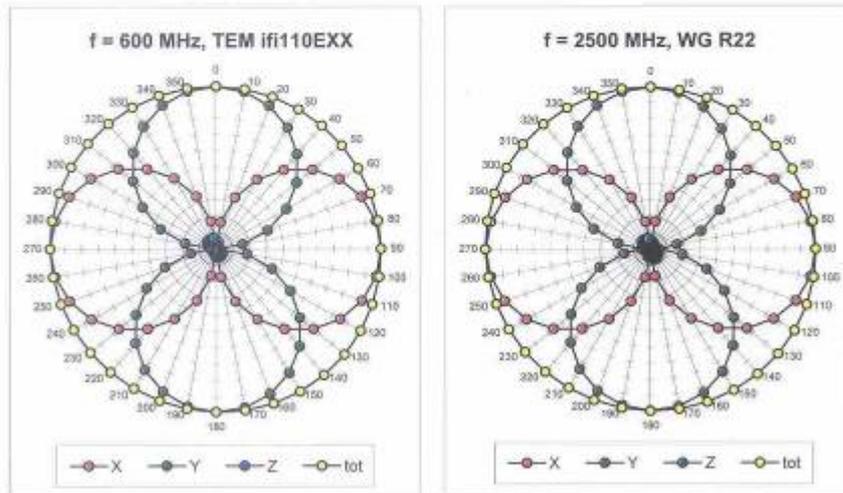


Uncertainty of Frequency Response of E-field: $\pm 6.3\%$ (k=2)

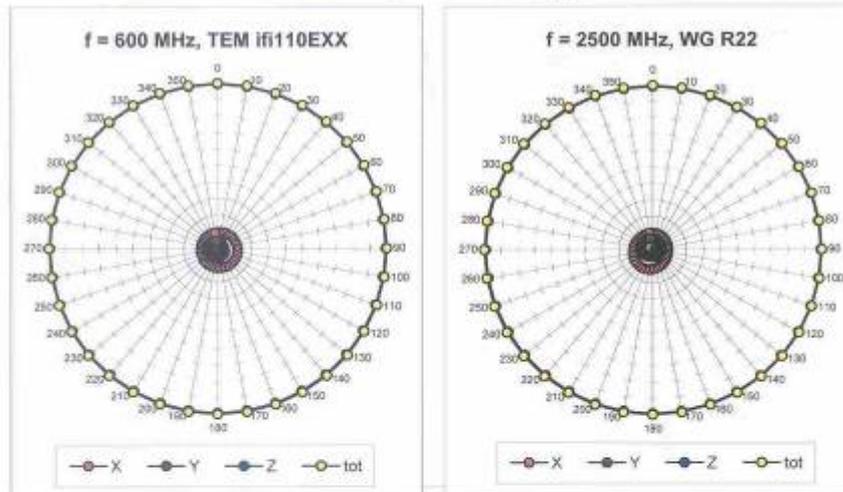
ER3DV6 SN:2428

October 20, 2009

Receiving Pattern (ϕ), $\vartheta = 0^\circ$



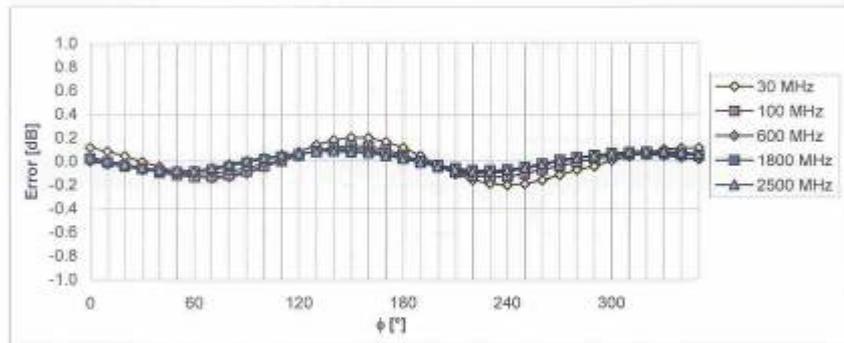
Receiving Pattern (ϕ), $\vartheta = 90^\circ$



ER3DV6 SN:2428

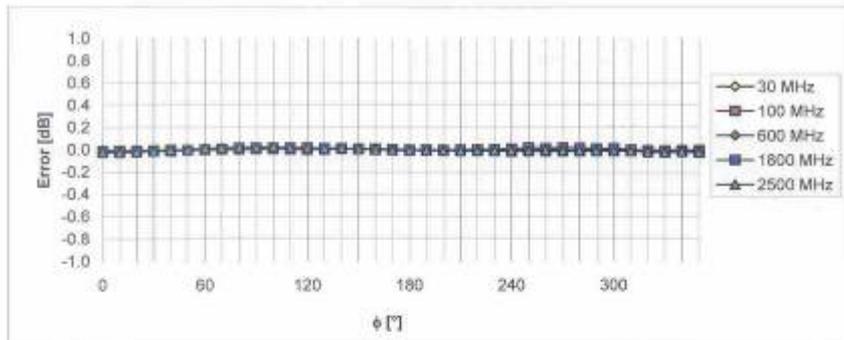
October 20, 2009

Receiving Pattern (ϕ), $\vartheta = 0^\circ$



Uncertainty of Axial Isotropy Assessment: $\pm 0.5\%$ (k=2)

Receiving Pattern (ϕ), $\vartheta = 90^\circ$

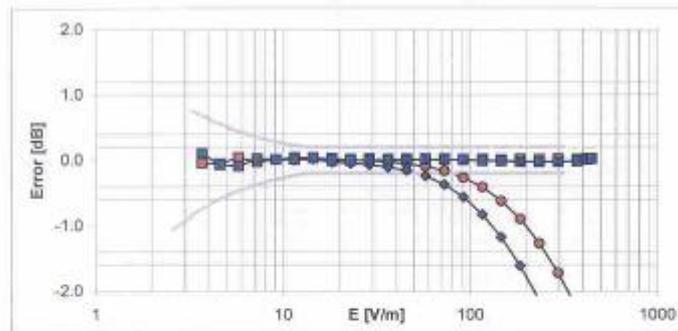
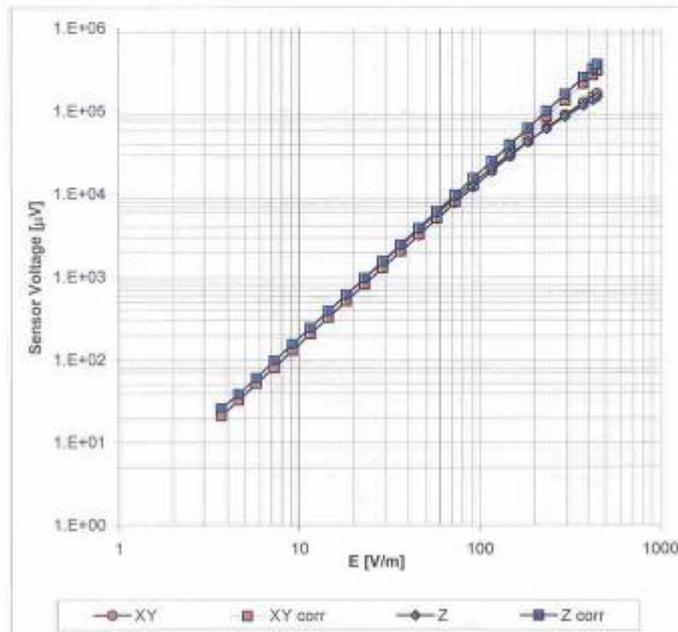


Uncertainty of Axial Isotropy Assessment: $\pm 0.5\%$ (k=2)

ER3DV6 SN:2428

October 20, 2009

Dynamic Range f(E-field)
(Waveguide R22, f = 1800 MHz)

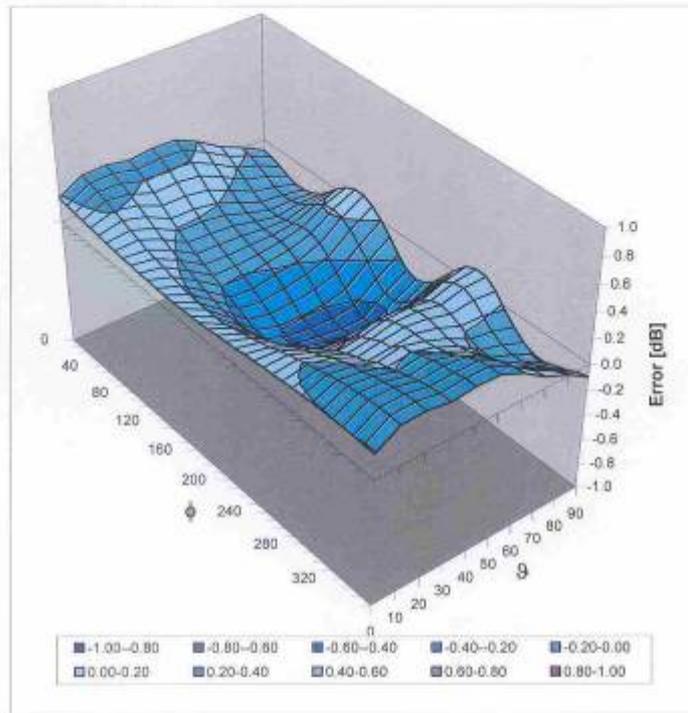


Uncertainty of Linearity Assessment: $\pm 0.6\%$ (k=2)

ER3DV6 SN:2428

October 20, 2009

Deviation from Isotropy in Air
Error (ϕ, ϑ), $f = 900$ MHz



Uncertainty of Spherical Isotropy Assessment: $\pm 2.6\%$ ($k=2$)

TA Technology (Shanghai) Co., Ltd.
Test Report

ER3DV6 SN:2428

October 20, 2009

Other Probe Parameters

Sensor Arrangement	Rectangular
Connector Angle (°)	-218.7
Mechanical Surface Detection Mode	enabled
Optical Surface Detection Mode	disabled
Probe Overall Length	337 mm
Probe Body Diameter	10 mm
Tip Length	10 mm
Tip Diameter	8.0 mm
Probe Tip to Sensor X Calibration Point	2.5 mm
Probe Tip to Sensor Y Calibration Point	2.5 mm
Probe Tip to Sensor Z Calibration Point	2.5 mm

TA Technology (Shanghai) Co., Ltd.

Test Report

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ANNEX D: H-Probe Calibration Certificate

**Calibration Laboratory of
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Zeughausstrasse 43, 8004 Zurich, Switzerland



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Accreditation No.: **SCS 108**

Client **TMC**

Certificate No: **H3-6260_Oct09**

CALIBRATION CERTIFICATE

Object: **H3DV6 - SN:6260**

Calibration procedure(s): **QA CAL-03.v5 and QA CAL-25.v2
Calibration procedure for H-field probes optimized for close near field
evaluations in air**

Calibration date: **October 20, 2009**

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).
The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration
Power meter E4419B	GB41293874	1-Apr-09 (No. 217-01030)	Apr-10
Power sensor E4412A	MY41495277	1-Apr-09 (No. 217-01030)	Apr-10
Power sensor E4412A	MY41498087	1-Apr-09 (No. 217-01030)	Apr-10
Reference 3 dB Attenuator	SN: S5054 (3c)	31-Mar-09 (No. 217-01026)	Mar-10
Reference 20 dB Attenuator	SN: S5096 (20b)	31-Mar-09 (No. 217-01026)	Mar-10
Reference 30 dB Attenuator	SN: S5129 (30b)	31-Mar-09 (No. 217-01027)	Mar-10
Reference Probe H3DV6	SN: 6182	3-Oct-09 (No. H3-6182_Oct09)	Oct-10
DAE4	SN: 789	19-Dec-08 (No. DAE4-789_Dec08)	Dec-09
Secondary Standards	ID #	Check Date (in house)	Scheduled Check
RF generator HP 8648C	US3642U01700	4-Aug-09 (in house check Oct-09)	In house check: Oct-11
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-09)	In house check: Oct10

	Name	Function	Signature
Calibrated by:	Marcel Fehr	Laboratory Technician	
Approved by:	Katja Pokovic	Technical Manager	

Issued: October 22, 2009

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Test Report

Report No. RZA1106-1087HAC01R1

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Accreditation No.: **SCS 108**

Glossary:

NORM _{x,y,z}	sensitivity in free space
DCP	diode compression point
CF	crest factor (1/duty_cycle) of the RF signal
A, B, C	modulation dependent linearization parameters
Polarization φ	φ rotation around probe axis
Polarization ϑ	ϑ rotation around an axis that is in the plane normal to probe axis (at measurement center), I.e., $\vartheta = 0$ is normal to probe axis
Connector Angle	information used in DASY system to align probe sensor X to the robot coordinate system

Calibration is Performed According to the Following Standards:

- IEEE Std 1309-2005, "IEEE Standard for calibration of electromagnetic field sensors and probes, excluding antennas, from 9 kHz to 40 GHz", December 2005.

Methods Applied and Interpretation of Parameters:

- NORM_{x,y,z}**: Assessed for E-field polarization $\vartheta = 0$ for XY sensors and $\vartheta = 90$ for Z sensor ($f \leq 900$ MHz in TEM-cell; $f > 1800$ MHz: R22 waveguide).
- X, Y, Z(f)**: $a_0 a_1 a_2 = X, Y, Z$ * frequency_response (see Frequency Response Chart).
- DCP_{x,y,z}**: DCP are numerical linearization parameters assessed based on the data of power sweep with CW signal (no uncertainty required). DCP does not depend on frequency nor media.
- A_{x,y,z}; B_{x,y,z}; C_{x,y,z}** are numerical linearization parameters assessed based on the data of power sweep for specific modulation signal. The parameters do not depend on frequency nor media.
- Spherical isotropy (3D deviation from isotropy)**: in a locally homogeneous field realized using an open waveguide setup.
- Sensor Offset**: The sensor offset corresponds to the offset of virtual measurement center from the probe tip (on probe axis). No tolerance required.
- Connector Angle**: The angle is assessed using the information gained by determining the $X_{a_0 a_1 a_2}$ (no uncertainty required).

H3DV6 SN:6260

October 20, 2009

Probe H3DV6

SN:6260

Manufactured:	September 7, 2007
Last calibrated:	December 13, 2007
Recalibrated:	October 20, 2009

Calibrated for DASY Systems

(Note: non-compatible with DASY2 system!)

TA Technology (Shanghai) Co., Ltd.

Test Report

H3DV6 SN:6260

October 20, 2009

DASY - Parameters of Probe: H3DV6 SN:6260

Basic Calibration Parameters

		Sensor X	Sensor Y	Sensor Z	Unc (k=2)
Norm (A/m / $\sqrt{\mu V}$)	a0	2.47E-3	2.49E-3	2.95E-3	$\pm 10.1\%$
Norm (A/m / $\sqrt{\mu V}$)	a1	-2.97E-5	5.62E-6	-4.47E-5	$\pm 10.1\%$
Norm (A/m / $\sqrt{\mu V}$)	a2	4.84E-5	4.36E-5	6.01E-5	$\pm 10.1\%$
DCP (mV) ¹		84.5	90.3	83.9	

Modulation Calibration Parameters

UID	Communication System Name	PAR		A dB	B dBuV	C	VR mV	Unc (k=2)
10000	CW	0.00	X	0.00	0.00	1.00	300	$\pm 1.5\%$
			Y	0.00	0.00	1.00	300	
			Z	0.00	0.00	1.00	300	

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

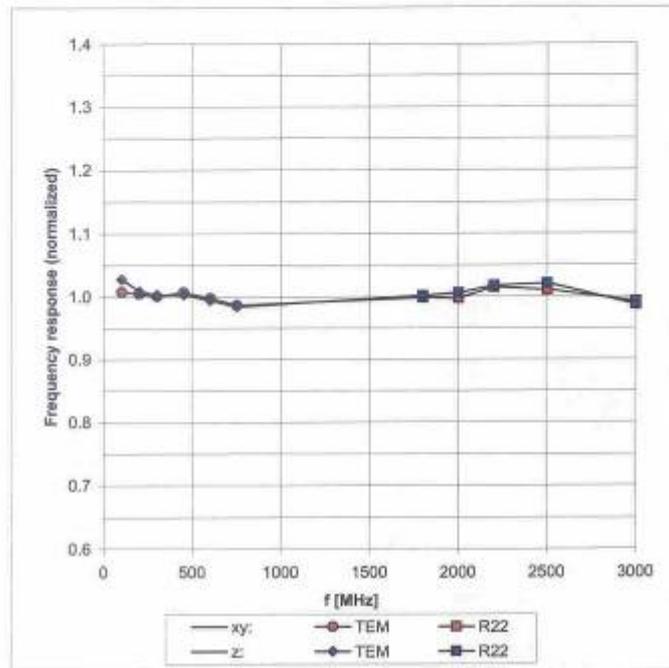
¹ numerical linearization parameter: uncertainty not required

H3DV6 SN:6260

October 20, 2009

Frequency Response of H-Field

(TEM-Cell:ifi110 EXX, Waveguide R22)

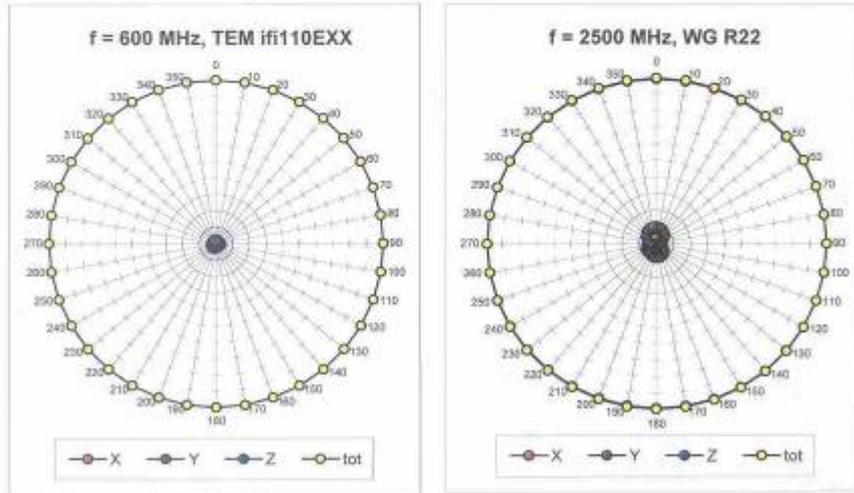


Uncertainty of Frequency Response of H-field: $\pm 6.3\%$ (k=2)

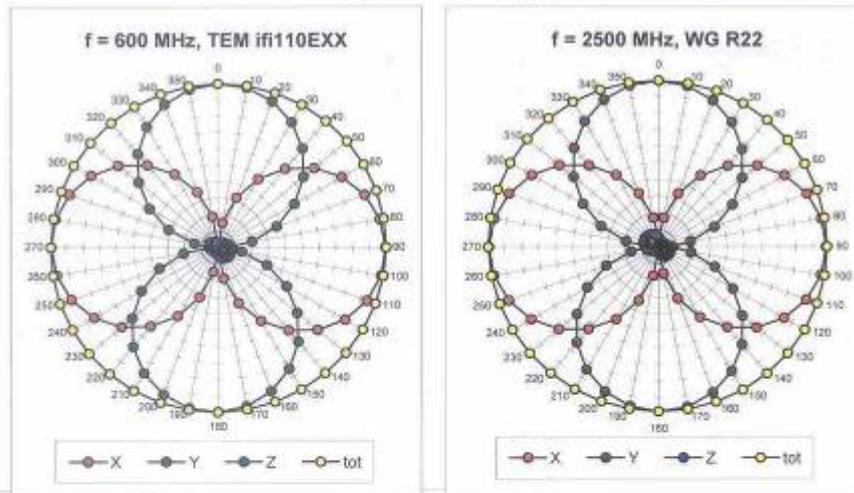
H3DV6 SN:6260

October 20, 2009

Receiving Pattern (ϕ), $\vartheta = 90^\circ$



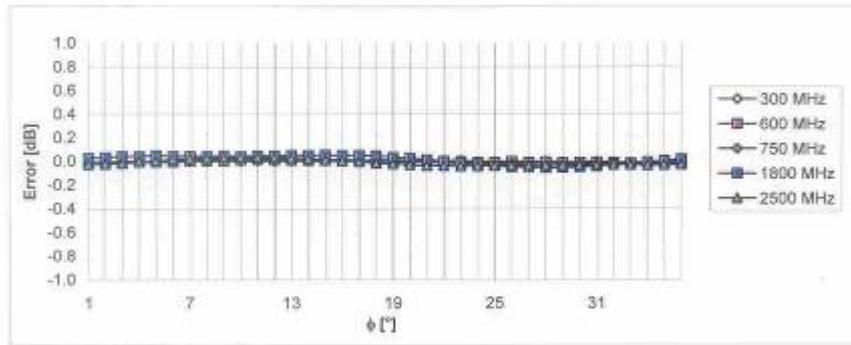
Receiving Pattern (ϕ), $\vartheta = 0^\circ$



H3DV6 SN:6260

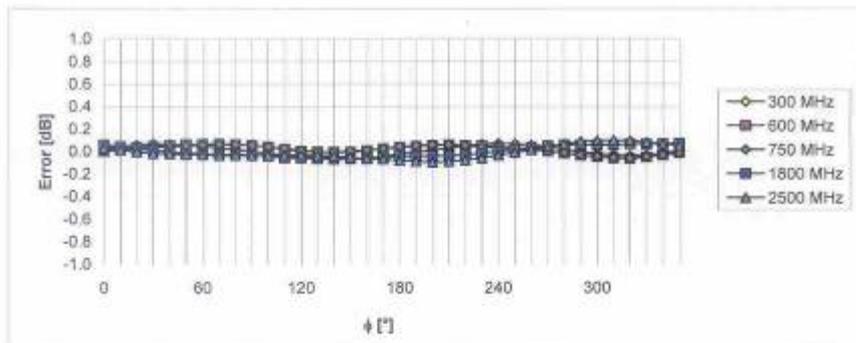
October 20, 2009

Receiving Pattern (ϕ), $\vartheta = 90^\circ$



Uncertainty of Axial Isotropy Assessment: $\pm 0.5\%$ (k=2)

Receiving Pattern (ϕ), $\vartheta = 0^\circ$

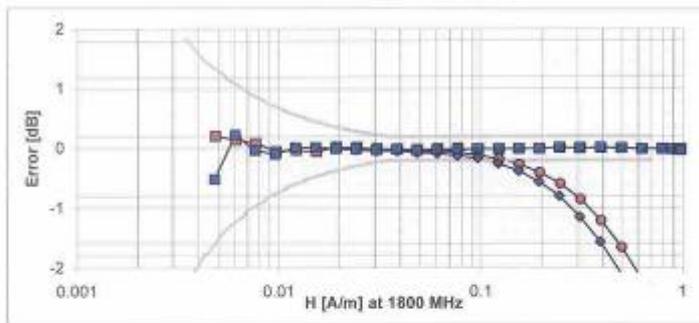
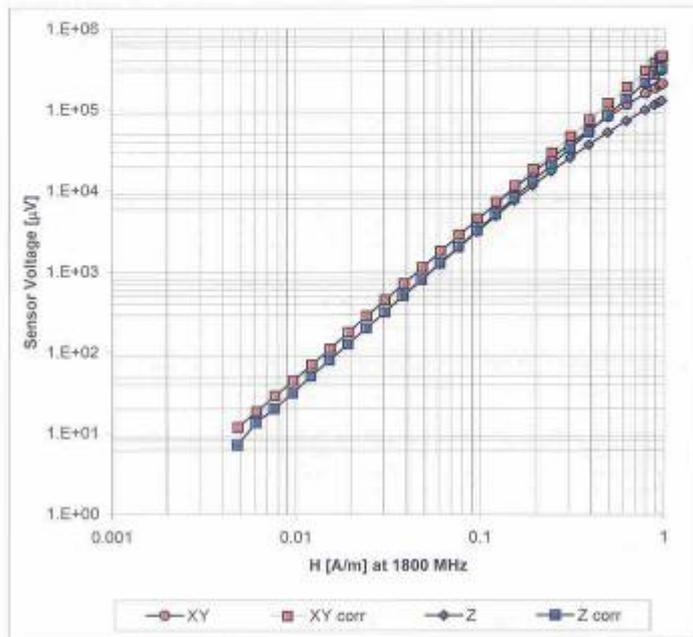


Uncertainty of Axial Isotropy Assessment: $\pm 0.5\%$ (k=2)

H3DV6 SN:6260

October 20, 2009

Dynamic Range f(H-field)
(Waveguide R22, f = 1800 MHz)

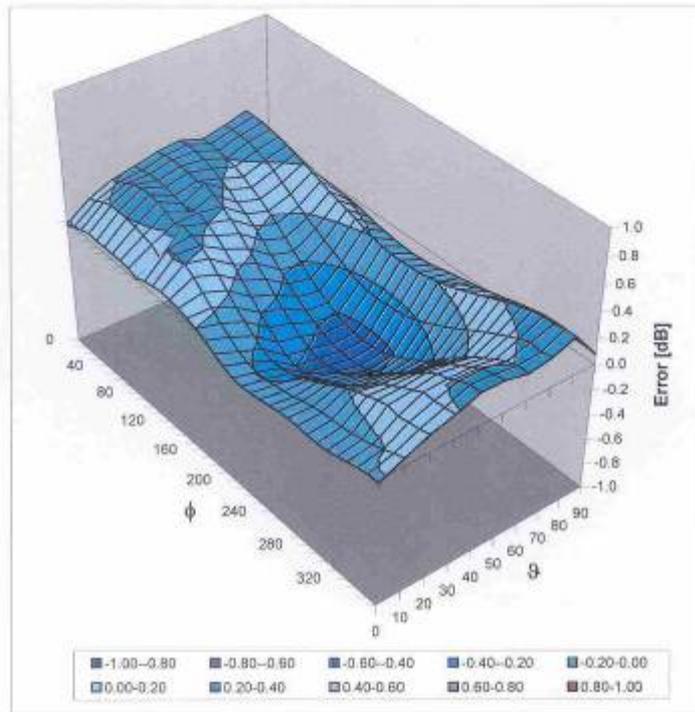


Uncertainty of Linearity Assessment: $\pm 0.6\%$ (k=2)

H3DV6 SN:6260

October 20, 2009

Deviation from Isotropy in Air
Error (ϕ , θ), $f = 900$ MHz



Uncertainty of Spherical Isotropy Assessment: $\pm 2.6\%$ ($k=2$)

H3DV6 SN:6260

October 20, 2009

Other Probe Parameters

Sensor Arrangement	Rectangular
Connector Angle (°)	-154.1
Mechanical Surface Detection Mode	enabled
Optical Surface Detection Mode	disabled
Probe Overall Length	337 mm
Probe Body Diameter	10 mm
Tip Length	20 mm
Tip Diameter	6.0 mm
Probe Tip to Sensor X Calibration Point	3 mm
Probe Tip to Sensor Y Calibration Point	3 mm
Probe Tip to Sensor Z Calibration Point	3 mm

TA Technology (Shanghai) Co., Ltd. Test Report

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ANNEX E: CD835V3 Dipole Calibration Certificate

**Calibration Laboratory of
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Zeughausstrasse 43, 8004 Zurich, Switzerland



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Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: **SCS 108**

Client **TA Technology (Auden)**

Certificate No: **CD835V3-1133_Apr09**

CALIBRATION CERTIFICATE

Object: **CD835V3 - SN: 1133**

Calibration procedure(s): **QA CAL-20.v4
Calibration procedure for dipoles in air**

Calibration date: **April 22, 2009**

Condition of the calibrated item: **In Tolerance**

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).
All calibrations have been conducted in the closed laboratory facility; environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration
Power meter EPM-442A	GB37480704	08-Oct-08 (No. 217-00898)	Oct-09
Power sensor HP 8461A	US37292783	08-Oct-08 (No. 217-00898)	Oct-09
Probe ER3DV6	SN: 2336	22-Dec-08 (No. ER3-2336_Dec08)	Dec-09
Probe H3DV6	SN: 6065	22-Dec-08 (No. H3-6065_Dec08)	Dec-09
DAE4	SN: 781	20-Feb-09 (No. DAE4-781_Feb09)	Feb-10
Secondary Standards	ID #	Check Date (in house)	Scheduled Check
Power meter R&S NRP	SN: 101748	23-Sep-08 (in house check Dec-08)	In house check: Dec-10
Power sensor R&S NRP-Z91	SN: 100711	25-Aug-08 (in house check Dec-08)	In house check: Dec-10
Power sensor R&S NRP-Z91	SN: 100712	25-Aug-08 (in house check Dec-08)	In house check: Dec-10
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-08)	In house check: Oct-09
RF generator E4433B	MY 41310391	03-Nov-04 (in house check Oct-07)	In house check: Oct-09

	Name	Function	Signature
Calibrated by:	Mike Mell	Laboratory Technician	<i>[Signature]</i>
Approved by:	Fin Bombolt	Technical Director	<i>[Signature]</i>

Issued: April 24, 2009

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Accreditation No.: **SCS 108**

References

- [1] ANSI-C63.19-2006
American National Standard for Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.
- [2] ANSI-C63.19-2007
American National Standard for Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

Methods Applied and Interpretation of Parameters:

- **Coordinate System:** y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes. In coincidence with the standards [1, 2], the measurement planes (probe sensor center) are selected to be at a distance of 10 mm above the top edge of the dipole arms.
- **Measurement Conditions:** Further details are available from the hardcopies at the end of the certificate. All figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- **Antenna Positioning:** The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY4 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- **Feed Point Impedance and Return Loss:** These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminated by applying the averaging function while moving the dipole in the air, at least 70cm away from any obstacles.
- **E-field distribution:** E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1, 2], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 10 mm (in z) above the top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, 10mm above the dipole surface.
- **H-field distribution:** H-field is measured with an isotropic H-field probe with 100mW forward power to the antenna feed point, in the x-y-plane. The scan area and sensor distance is equivalent to the E-field scan. The maximum of the field is available at the center (subgrid 5) above the feed point. The H-field value stated as calibration value represents the maximum of the interpolated H-field, 10mm above the dipole surface at the feed point.

TA Technology (Shanghai) Co., Ltd.

Test Report

1 Measurement Conditions

DASY system configuration, as far as not given on page 1.

DASY Version	DASY4	V4.7 B80
DASY PP Version	SEMCAD	V1.8 B186
Phantom	HAC Test Arch	SD HAC P01 BA, #1070
Distance Dipole Top - Probe Center	10 mm	
Scan resolution	dx, dy = 5 mm	area = 20 x 180 mm
Frequency	835 MHz ± 1 MHz	
Forward power at dipole connector	20.0 dBm = 100mW	
Input power drift	< 0.05 dB	

2 Maximum Field values

H-field 10 mm above dipole surface	condition	interpolated maximum
Maximum measured	100 mW forward power	0.446 A/m

Uncertainty for H-field measurement: 8.2% (k=2)

E-field 10 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end-	100 mW forward power	158.2 V/m
Maximum measured above low end	100 mW forward power	157.3 V/m
Averaged maximum above arm	100 mW forward power	157.8 V/m

Uncertainty for E-field measurement: 12.8% (k=2)

3 Appendix

3.1 Antenna Parameters

Frequency	Return Loss	Impedance
800 MHz	18.2 dB	(43.3 – j12.9) Ohm
835 MHz	33.2 dB	(49.3 + j2.1) Ohm
900 MHz	17.4 dB	(53.5 – j13.6) Ohm
950 MHz	20.0 dB	(44.3 + j7.5) Ohm
960 MHz	14.8 dB	(53.2 + j18.8) Ohm

3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

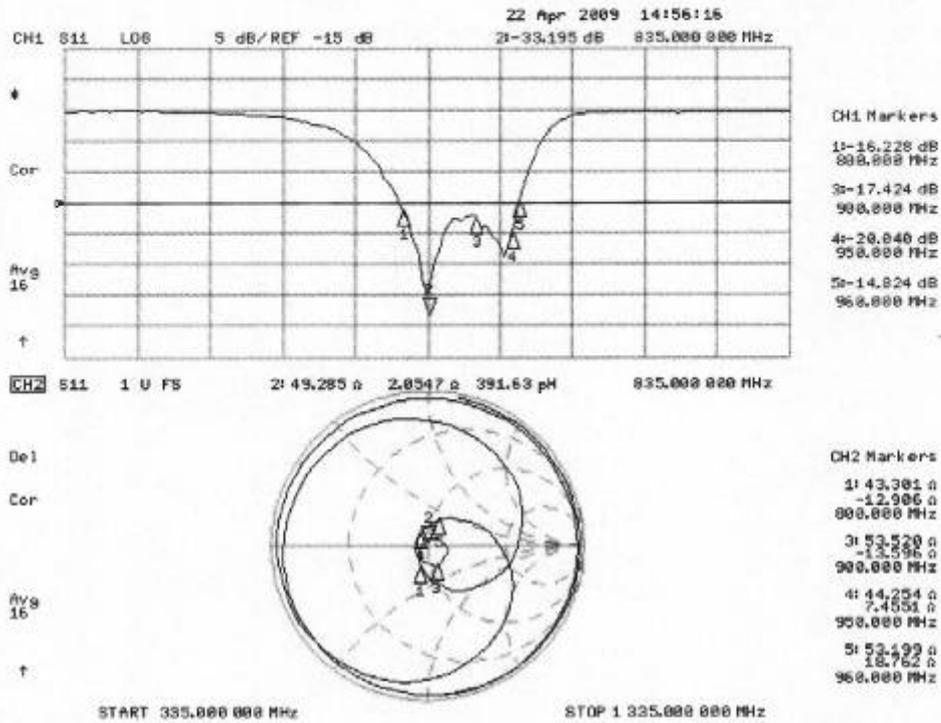
The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

3.3 Measurement Sheets

3.3.1 Return Loss and Smith Chart



3.3.2 DASY4 H-field Result

Date/Time: 21.04.2009 13:38:21

Test Laboratory: SPEAG Lab 2

DUT: HAC-Dipole 835 MHz; Type: D835V3; Serial: 1133
 Communication System: CW; Frequency: 835 MHz; Duty Cycle: 1:1
 Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³
 Phantom section: RF Section
 Measurement Standard: DASY4 (High Precision Assessment)

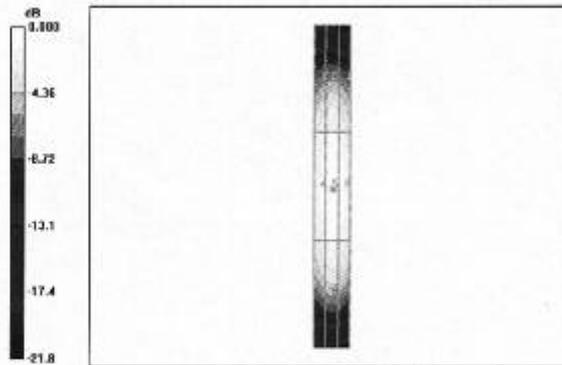
DASY4 Configuration:

- Probe: H3DV6 - SN6065; ; Calibrated: 22.12.2008
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 20.02.2009
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1):
 Measurement grid: dx=5mm, dy=5mm
 Maximum value of peak Total field = 0.446 A/m
 Probe Modulation Factor = 1.00
 Device Reference Point: 0.000, 0.000, -6.30 mm
 Reference Value = 0.472 A/m; Power Drift = -0.006 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.364 M4	0.385 M4	0.368 M4
Grid 4	Grid 5	Grid 6
0.417 M4	0.446 M4	0.426 M4
Grid 7	Grid 8	Grid 9
0.365 M4	0.393 M4	0.376 M4



0 dB = 0.446 A/m

3.3.3 DASY4 E-field Result

Date/Time: 22.04.2009 12:51:53

Test Laboratory: SPEAG Lab 2

DUT: HAC-Dipole 835 MHz; Type: D835V3; Serial: 1133
 Communication System: CW; Frequency: 835 MHz; Duty Cycle: 1:1
 Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³
 Phantom section: RF Section
 Measurement Standard: DASY4 (High Precision Assessment)

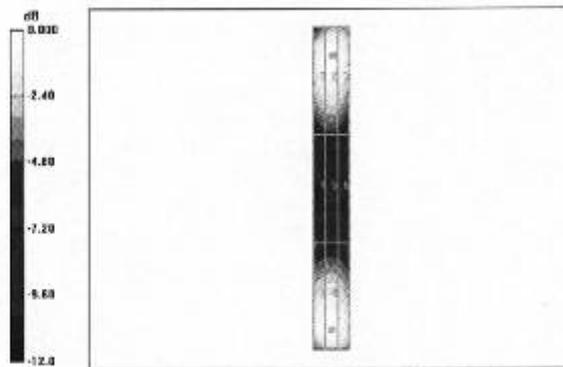
DASY4 Configuration:

- Probe: ER3DV6 - SN2336; ConvF(1, 1, 1); Calibrated: 22.12.2008
- Sensor-Surface: (Fix Surface)
- Electronics: DA4 Sn781; Calibrated: 20.02.2009
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1):
 Measurement grid: dx=5mm, dy=5mm
 Maximum value of peak Total field = 158.2 V/m
 Probe Modulation Factor = 1.00
 Device Reference Point: 0.000, 0.000, -6.30 mm
 Reference Value = 105.8 V/m; Power Drift = -0.013 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
152.4 M4	158.2 M4	154.6 M4
Grid 4	Grid 5	Grid 6
84.6 M4	86.9 M4	84.2 M4
Grid 7	Grid 8	Grid 9
151.7 M4	157.3 M4	152.4 M4



0 dB = 158.2V/m

TA Technology (Shanghai) Co., Ltd. Test Report

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ANNEX F: CD1880V3 Dipole Calibration Certificate

**Calibration Laboratory of
Schmid & Partner
Engineering AG**
Zaughausstrasse 43, 8004 Zurich, Switzerland



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S Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS)
The Swiss Accreditation Service is one of the signatories to the EA
Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: **SCS 108**

Client **Auden**

Certificate No: **CD1880V3-1135_Jan10**

CALIBRATION CERTIFICATE

Object **CD1880V3 - SN: 1135**

Calibration procedure(s) **QA CAL-20.v5
Calibration procedure for dipoles in air**

Calibration date: **January 13, 2010**

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).
All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration
Power meter EPM-442A	GB37490704	06-Oct-09 (No. 217-01086)	Oct-10
Power sensor HP 8481A	US37292783	06-Oct-09 (No. 217-01086)	Oct-10
Probe ER3DV6	SN: 2336	30-Dec-09 (No. ER3-2336_Dec09)	Dec-10
Probe H3DV6	SN: 6065	30-Dec-09 (No. H3-6065_Dec09)	Dec-10
DAE4	SN: 781	30-Nov-09 (No. DAE4-781_Nov09)	Nov-10

Secondary Standards	ID #	Check Date (in house)	Scheduled Check
Power meter Agilent 4419B	SN: GB42420181	09-Oct-09 (in house check Oct-09)	In house check: Oct-10
Power sensor HP 8482H	SN: 3318A09450	09-Oct-09 (in house check Oct-09)	In house check: Oct-10
Power sensor HP 8482A	SN: US37295597	09-Oct-09 (in house check Oct-09)	In house check: Oct-10
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-09)	In house check: Oct-10
RF generator E4433B	MY 41000675	03-Nov-04 (in house check Oct-09)	In house check: Oct-11

Calibrated by: **Claudio Leubler** Name: Claudio Leubler Function: Laboratory Technician

Approved by: **Katja Pokovic** Name: Katja Pokovic Function: Technical Manager

Signature

Issued: January 19, 2010

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

Calibration Laboratory of
Schmid & Partner
Engineering AG
Zeughausstrasse 43, 8004 Zurich, Switzerland



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The Swiss Accreditation Service is one of the signatories to the EA
Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 108

References

- [1] ANSI-C63.19-2006
American National Standard for Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.
- [2] ANSI-C63.19-2007
American National Standard for Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

Methods Applied and Interpretation of Parameters:

- **Coordinate System:** y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes. In coincidence with the standards [1, 2], the measurement planes (probe sensor center) are selected to be at a distance of 10 mm above the top edge of the dipole arms.
- **Measurement Conditions:** Further details are available from the hardcopies at the end of the certificate. All figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- **Antenna Positioning:** The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- **Feed Point Impedance and Return Loss:** These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminated by applying the averaging function while moving the dipole in the air, at least 70cm away from any obstacles.
- **E-field distribution:** E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1, 2], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 10 mm (in z) above the top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, 10mm above the dipole surface.
- **H-field distribution:** H-field is measured with an isotropic H-field probe with 100mW forward power to the antenna feed point, in the x-y-plane. The scan area and sensor distance is equivalent to the E-field scan. The maximum of the field is available at the center (subgrid 5) above the feed point. The H-field value stated as calibration value represents the maximum of the interpolated H-field, 10mm above the dipole surface at the feed point.

TA Technology (Shanghai) Co., Ltd.

Test Report

1. Measurement Conditions

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V5.2 B157
DASY PP Version	SEMCAD X	V14.0 B57
Phantom	HAC Test Arch	SD HAC P01 BA, #1070
Distance Dipole Top - Probe Center	10 mm	
Scan resolution	dx, dy = 5 mm	area = 20 x 90 mm
Frequency	1880 MHz ± 1 MHz	
Forward power at dipole connector	20.0 dBm = 100mW	
Input power drift	< 0.05 dB	

2. Maximum Field values

H-field 10 mm above dipole surface	condition	Interpolated maximum
Maximum measured	100 mW forward power	0.475 A/m

Uncertainty for H-field measurement: 8.2% (k=2)

E-field 10 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end	100 mW forward power	142.9 V/m
Maximum measured above low end	100 mW forward power	139.7 V/m
Averaged maximum above arm	100 mW forward power	141.3 V/m

Uncertainty for E-field measurement: 12.8% (k=2)

3. Appendix

3.1 Antenna Parameters

Frequency	Return Loss	Impedance
1710 MHz	18.8 dB	(47.5 + j10.9) Ohm
1880 MHz	21.2 dB	(51.5 + j8.7) Ohm
1900 MHz	21.8 dB	(54.4 + j7.3) Ohm
1950 MHz	26.4 dB	(54.9 - j1.1) Ohm
2000 MHz	20.0 dB	(41.0 - j0.8) Ohm

3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

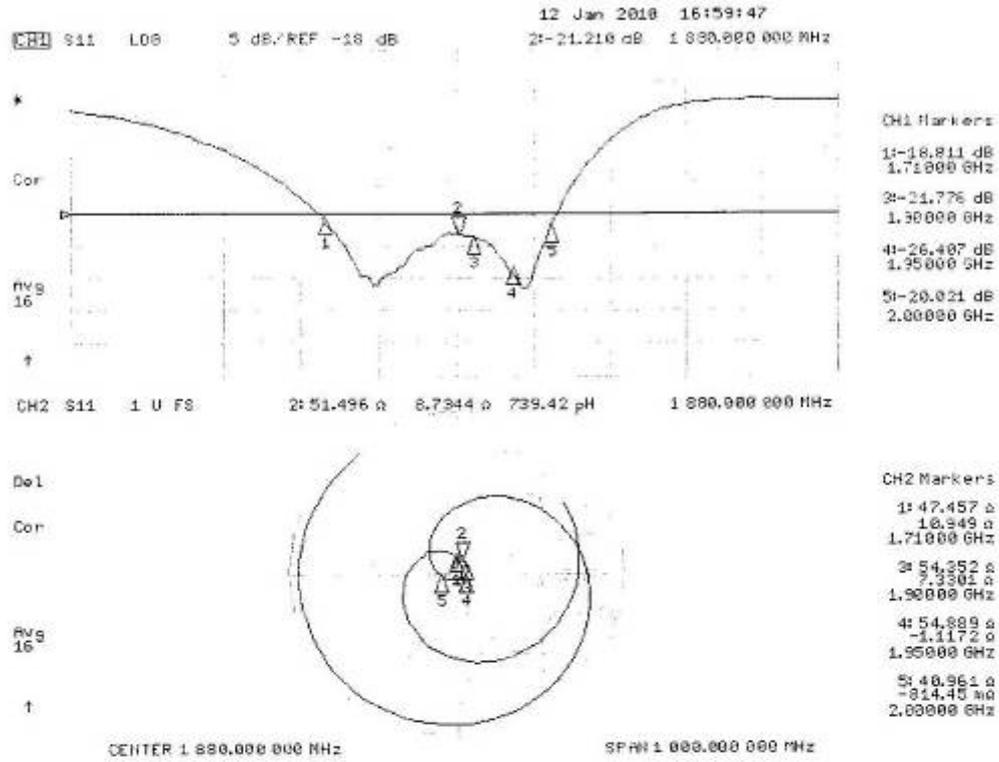
TA Technology (Shanghai) Co., Ltd. Test Report

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3.3 Measurement Sheets

3.3.1 Return Loss and Smith Chart



3.3.2 DASY4 H-Field Result

Date/Time: 13.01.2010 12:17:00

Test Laboratory: SPEAG Lab2

HAC_RF_CD1880_1135_100113_H_CL

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: 1135

Communication System: CW; Frequency: 1880 MHz

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6065; ; Calibrated: 30.12.2009
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 30.11.2009
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY5, V5.2 Build 157; SEMCAD X Version 14.0 Build 57

Dipole H-Field measurement @ 1880MHz/H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.475 A/m

Probe Modulation Factor = 1

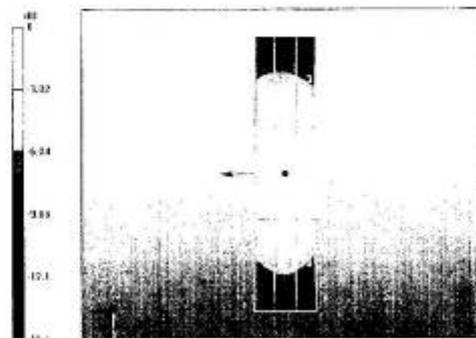
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.503 A/m; Power Drift = -0.017 dB

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.421 M2	Grid 2 0.436 M2	Grid 3 0.410 M2
Grid 4 0.458 M2	Grid 5 0.475 M2	Grid 6 0.447 M2
Grid 7 0.412 M2	Grid 8 0.431 M2	Grid 9 0.407 M2



0 dB = 0.475A/m

3.3.3 DASY4 E-Field Result

Date/Time: 13.01.2010 13:42:51

Test Laboratory: SPEAG Lab2

HAC_RF_CD1880_1135_100113_E_CL

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: 1135

Communication System: CW; Frequency: 1880 MHz

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2336; ConvF(1, 1, 1); Calibrated: 30.12.2009
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 30.11.2009
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY5, V5.2 Build 157; SEMCAD X Version 14.0 Build 57

Dipole E-Field measurement @ 1880MHz/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 142.9 V/m

Probe Modulation Factor = 1

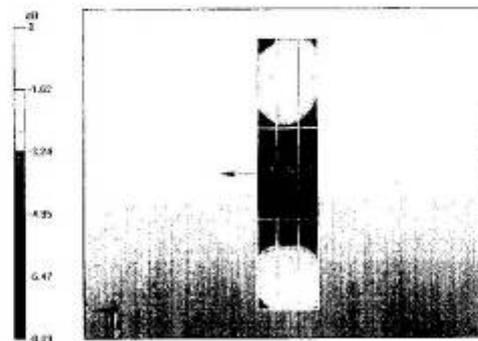
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 162.1 V/m; Power Drift = -0.010 dB

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak E-field in V/m

Grid 1 136.2 M2	Grid 2 139.7 M2	Grid 3 135.5 M2
Grid 4 93.1 M3	Grid 5 95.1 M3	Grid 6 90.7 M3
Grid 7 135.2 M2	Grid 8 142.9 M2	Grid 9 140.6 M2



0 dB = 142.9V/m

TA Technology (Shanghai) Co., Ltd. Test Report

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ANNEX G: DAE4 Calibration Certificate

**Calibration Laboratory of
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Engineering AG**
Zeughausstrasse 43, 8004 Zurich, Switzerland



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The Swiss Accreditation Service is one of the signatories to the EA
Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: **SCS 108**

Client **TA - SH (Auden)**

Certificate No: **DAE4-871_Nov10**

CALIBRATION CERTIFICATE

Object **DAE4 - SD 000 D04 BJ - SN: 871**

Calibration procedure(s) **QA CAL-06.v22
Calibration procedure for the data acquisition electronics (DAE)**

Calibration date: **November 18, 2010**

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).
The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration
Keithley Multimeter Type 2001	SN: 0810278	28-Sep-10 (No:10376)	Sep-11
Secondary Standards	ID #	Check Date (in house)	Scheduled Check
Calibrator Box V1.1	SE UMS 006 AB 1004	07-Jun-10 (in house check)	In house check: Jun-11

	Name	Function	Signature
Calibrated by:	Andrea Guntli	Technician	
Approved by:	Fin Bornholt	R&D Director	

Issued: November 18, 2010

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

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Test Report

Report No. RZA1106-1087HAC01R1

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**Calibration Laboratory of
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Engineering AG**
Zeughausstrasse 43, 8004 Zurich, Switzerland



S Schweizerischer Kalibrierdienst
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Accredited by the Swiss Accreditation Service (SAS)
The Swiss Accreditation Service is one of the signatories to the EA
Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: **SCS 108**

Glossary

DAE data acquisition electronics
Connector angle information used in DASY system to align probe sensor X to the robot coordinate system.

Methods Applied and Interpretation of Parameters

- **DC Voltage Measurement:** Calibration Factor assessed for use in DASY system by comparison with a calibrated instrument traceable to national standards. The figure given corresponds to the full scale range of the voltmeter in the respective range.
- **Connector angle:** The angle of the connector is assessed measuring the angle mechanically by a tool inserted. Uncertainty is not required.
- The following parameters as documented in the Appendix contain technical information as a result from the performance test and require no uncertainty.
 - **DC Voltage Measurement Linearity:** Verification of the Linearity at +10% and -10% of the nominal calibration voltage. Influence of offset voltage is included in this measurement.
 - **Common mode sensitivity:** Influence of a positive or negative common mode voltage on the differential measurement.
 - **Channel separation:** Influence of a voltage on the neighbor channels not subject to an input voltage.
 - **AD Converter Values with inputs shorted:** Values on the internal AD converter corresponding to zero input voltage
 - **Input Offset Measurement:** Output voltage and statistical results over a large number of zero voltage measurements.
 - **Input Offset Current:** Typical value for information; Maximum channel input offset current, not considering the input resistance.
 - **Input resistance:** Typical value for information: DAE input resistance at the connector, during internal auto-zeroing and during measurement.
 - **Low Battery Alarm Voltage:** Typical value for information. Below this voltage, a battery alarm signal is generated.
 - **Power consumption:** Typical value for information. Supply currents in various operating modes.

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Test Report

DC Voltage Measurement

A/D - Converter Resolution nominal

High Range: 1LSB = 6.1 μ V, full range = -100...+300 mV
Low Range: 1LSB = 61nV, full range = -1.....+3mV

DASY measurement parameters: Auto Zero Time: 3 sec; Measuring time: 3 sec

Calibration Factors	X	Y	Z
High Range	404.757 \pm 0.1% (k=2)	404.740 \pm 0.1% (k=2)	405.181 \pm 0.1% (k=2)
Low Range	3.98219 \pm 0.7% (k=2)	3.93489 \pm 0.7% (k=2)	3.96831 \pm 0.7% (k=2)

Connector Angle

Connector Angle to be used in DASY system	90.0 \pm 1 $^{\circ}$
---	-------------------------

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Test Report

Appendix

1. DC Voltage Linearity

High Range	Reading (μV)	Difference (μV)	Error (%)
Channel X + Input	200001.2	-1.56	-0.00
Channel X + Input	20000.71	0.71	0.00
Channel X - Input	-19997.87	1.63	-0.01
Channel Y + Input	199994.3	1.99	0.00
Channel Y + Input	19998.92	-1.08	-0.01
Channel Y - Input	-20000.26	-0.76	0.00
Channel Z + Input	200009.2	-1.04	-0.00
Channel Z + Input	19998.70	-1.10	-0.01
Channel Z - Input	-20000.16	-0.76	0.00

Low Range	Reading (μV)	Difference (μV)	Error (%)
Channel X + Input	2000.1	0.16	0.01
Channel X + Input	199.58	-0.52	-0.26
Channel X - Input	-200.79	-0.89	0.45
Channel Y + Input	1999.9	-0.03	-0.00
Channel Y + Input	199.45	-0.55	-0.27
Channel Y - Input	-200.31	-0.41	0.21
Channel Z + Input	2000.1	0.33	0.02
Channel Z + Input	199.13	-0.77	-0.38
Channel Z - Input	-201.47	-1.37	0.69

2. Common mode sensitivity

DASY measurement parameters: Auto Zero Time: 3 sec; Measuring time: 3 sec

	Common mode Input Voltage (mV)	High Range Average Reading (μV)	Low Range Average Reading (μV)
Channel X	200	14.25	12.86
	-200	-12.68	-14.21
Channel Y	200	-10.04	-10.39
	-200	9.20	9.17
Channel Z	200	-0.85	-1.40
	-200	-0.34	-0.31

3. Channel separation

DASY measurement parameters: Auto Zero Time: 3 sec; Measuring time: 3 sec

	Input Voltage (mV)	Channel X (μV)	Channel Y (μV)	Channel Z (μV)
Channel X	200	-	2.85	0.69
Channel Y	200	2.41	-	2.73
Channel Z	200	2.54	0.73	-

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Test Report

4. AD-Converter Values with inputs shorted

DASY measurement parameters: Auto Zero Time: 3 sec; Measuring time: 3 sec

	High Range (LSB)	Low Range (LSB)
Channel X	15920	15517
Channel Y	16171	16732
Channel Z	15803	16474

5. Input Offset Measurement

DASY measurement parameters: Auto Zero Time: 3 sec; Measuring time: 3 sec

Input 10M Ω

	Average (μ V)	min. Offset (μ V)	max. Offset (μ V)	Std. Deviation (μ V)
Channel X	0.03	-2.35	0.86	0.43
Channel Y	-0.50	-1.49	-0.49	0.38
Channel Z	-0.92	-2.21	0.14	0.44

6. Input Offset Current

Nominal Input circuitry offset current on all channels: <25fA

7. Input Resistance (Typical values for information)

	Zeroing (kOhm)	Measuring (MOhm)
Channel X	200	200
Channel Y	200	200
Channel Z	200	200

8. Low Battery Alarm Voltage (Typical values for information)

Typical values	Alarm Level (VDC)
Supply (+ Vcc)	+7.9
Supply (- Vcc)	-7.6

9. Power Consumption (Typical values for information)

Typical values	Switched off (mA)	Stand by (mA)	Transmitting (mA)
Supply (+ Vcc)	+0.01	+6	+14
Supply (- Vcc)	-0.01	-8	-9